Advance Information

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MPC857T Hardware Specifications



This document contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MPC857T (refer to Table 1). This document contains the following topics:

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Part I Overview

The MPC857T is a derivative of Motorola's MC68360 Quad Integrated Communications Controller (QUICCTM) and part of the PowerQUICCTM family of devices. It is a versatile single-chip integrated microprocessor and peripheral combination that can be used in a variety of controller applications and communications and networking systems. The MPC8577T provides enhanced ATM functionality over that of other ATM-enabled members of the MPC860 family.

The CPU on the MPC857T is a 32-bit MPC8xx core that incorporates memory management units (MMUs) and instruction and data caches. The communications processor module (CPM) from the MC68360 QUICC has been enhanced by the addition of the inter-integrated controller (I²C) channel. The memory controller has been enhanced, enabling the MPC857T

Features

to support any type of memory, including high-performance memories and new types of DRAMs. A PCMCIA socket controller supports up to two sockets. A real-time clock has also been integrated.

Table 1 shows the functionality supported by the MPC857T and MPC857DSL.

Table 1. MPC857T Functionality

Part Instruction Cache MPC857T 4 Kbyte MPC857DSL 4 Kbyte	Ca	ache	Ethe		
	Data Cache	10T 10/100		SCC	
MPC857T	4 Kbyte	4 Kbyte	Up to 4	1	1
MPC857DSL	4 Kbyte	4 Kbyte	Up to 4	1	1

Unless otherwise specified, the PowerQUICC unit is referred to as the MPC857T in this document.

Part II Features

The following list summarizes the key MPC857T features:

- Embedded single-issue, 32-bit MPC8xx core (implementing the PowerPC architecture) with thirty-two 32-bit general-purpose registers (GPRs)
 - The core performs branch prediction with conditional prefetch, without conditional execution
 - 4-Kbyte data cache and 4- Kbyte instruction cache (see Table 1).
 - 4-Kbyte instruction cache is two-way, set-associative with 128 sets.
 - 4-Kbyte data cache is two-way, set-associative with 128 sets.
 - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks.
 - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis.
 - MMU with 32-entry TLB, fully associative instruction and data TLBs
 - MMU supports multiple page sizes of 4, 16, and 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and 16 protection groups
 - Advanced on-chip-emulation debug mode
- The MPC857T provides enhanced ATM functionality over that of the MPC860SAR. The MPC857T adds major new features available in "enhanced SAR" (ESAR) mode, including the following:
 - Multiple APC priority levels available to support a range of traffic pace requirements
 - Port-to-port switching capability without the need for RAM-based microcode
 - Simultaneous MII (100Base-T) and UTOPIA (half-duplex) capability
 - Optional statistical cell counters per PHY
 - Parameter RAM for both SPI and I²C can be relocated without RAM-based microcode.
 - Supports full-duplex UTOPIA master (ATM side) operation using a "split" bus
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
- 32 address lines

- Operates at up to 80 MHz
- Memory controller (eight banks)
 - Contains complete dynamic RAM (DRAM) controller
 - Each bank can be a chip select or RAS to support a DRAM bank
 - Up to 30 wait states programmable per memory bank
 - Glueless interface to DRAM, SIMMS, SRAM, EPROMs, flash EPROMs, and other memory devices.
 - DRAM controller programmable to support most size and speed memory interfaces
 - Four \overline{CAS} lines, four \overline{WE} lines, one \overline{OE} line
 - Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
 - Variable block sizes (32 Kbyte–256 Mbyte)
 - Selectable write protection
 - On-chip bus arbitration logic
- General-purpose timers
 - Four 16-bit timers or two 32-bit timers
 - Gate mode can enable/disable counting
 - Interrupt can be masked on reference match and event capture
- Fast Ethernet controller (FEC)
 - Simultaneous MII (100Base-T) and UTOPIA operation when using the UTOPIA multiplexed bus.
- System integration unit (SIU)
 - Bus monitor
 - Software watchdog
 - Periodic interrupt timer (PIT)
 - Low-power stop mode
 - Clock synthesizer
 - Decrementer, time base, and real-time clock (RTC) from the PowerPC architecture
 - Reset controller
 - IEEE 1149.1 test access port (JTAG)
- Interrupts
 - Seven external interrupt request (IRQ) lines
 - 12 port pins with interrupt capability
 - 20 internal interrupt sources
 - Programmable highest priority request
- Communications processor module (CPM)
 - RISC controller
 - Communication-specific commands (for example, GRACEFUL STOP TRANSMIT, ENTER HUNT MODE, and RESTART TRANSMIT)
 - Supports continuous mode transmission and reception on all serial channels

Features

- Up to 8-Kbytes of dual-port RAM
- 10 serial DMA (SDMA) channels
- Three parallel I/O registers with open-drain capability
- Four baud rate generators
 - Independent (can be connected to any SCC or SMC)
 - Allow changes during operation
 - Autobaud support option
- One SCC (serial communication controller) (The MPC857DSL supports ethernet only)
 - Serial ATM capability
 - Ethernet/IEEE 802.3 supporting full 10-Mbps operation
 - HDLC/SDLC
 - HDLC bus (implements an HDLC-based local area network (LAN))
 - Asynchronous HDLC to support PPP (point-to-point protocol)
 - AppleTalk
 - Universal asynchronous receiver transmitter (UART)
 - Synchronous UART
 - Serial infrared (IrDA)
 - Binary synchronous communication (BISYNC)
 - Totally transparent (bit streams)
 - Totally transparent (frame based with optional cyclic redundancy check (CRC))
- Two SMCs (serial management channels) (The MPC857DSL has one SMC, for UART)
 - UART
 - Transparent
 - General circuit interface (GCI) controller
 - Can be connected to the time-division multiplexed (TDM) channel
- One serial peripheral interface (SPI)
 - Supports master and slave modes
 - Supports multiple-master operation on the same bus
- One inter-integrated circuit (I²C) port
 - Supports master and slave modes
 - Multiple-master environment support
- Time-slot assigner (TSA) (The MPC857DSL does not have the TSA)
 - Allows SCC and SMCs to run in multiplexed and/or non-multiplexed operation
 - Supports T1, CEPT, PCM highway, user defined
 - 1- or 8-bit resolution
 - Allows independent transmit and receive routing, frame synchronization, clocking
 - Allows dynamic changes
 - Can be internally connected to three serial channels (one SCC and two SMCs)

- Parallel interface port (PIP)
 - Centronics interface support
 - Supports fast connection between compatible ports on MPC857T or MC68360
- PCMCIA interface
 - Master (socket) interface, release 2.1 compliant
 - Supports two independent PCMCIA sockets
 - 8 memory or I/O windows supported
- Low power support
 - Full on—All units fully powered
 - Doze—Core functional units disabled except time base decrementer, PLL, memory controller, RTC, and CPM in low-power standby
 - Sleep—All units disabled except RTC, PIT, time base, and decrementer with PLL active for fast wake up
 - Deep sleep—All units disabled including PLL except RTC, PIT, time base, and decrementer.
 - Power down mode— All units powered down except PLL, RTC, PIT, time base and decrementer
- Debug interface
 - Eight comparators: four operate on instruction address, two operate on data address, and two operate on data
 - Supports conditions: = <>
 - Each watchpoint can generate a break point internally
- 3.3 V operation with 5-V TTL compatibility except EXTAL and EXTCLK
- 357-pin ball grid array (BGA) package

The MPC857T is comprised of three modules that each use the 32-bit internal bus—the MPC8xx core, the system integration unit (SIU), and the communication processor module (CPM). The MPC857T block diagram is shown in Figure 2.

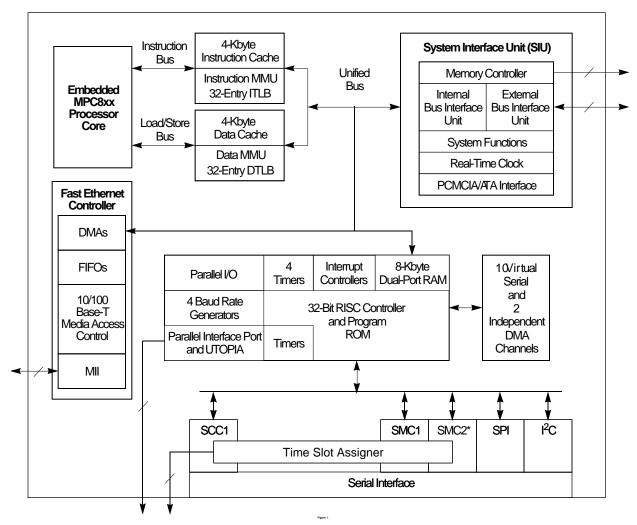


Figure 2. MPC857T Block Diagram

Part III Maximum Tolerated Ratings

This section provides the maximum tolerated voltage and temperature ranges for the MPC857T. Table 2 provides the maximum ratings.

Table 2. Maximum Tolerated Ratings

(GND = 0V)

Rating	Symbol	Value	Unit
Supply voltage ¹	VDDH	-0.3 to 4.0	V
	VDDL	-0.3 to 4.0	V
	KAPWR	-0.3 to 4.0	V
	VDDSYN	-0.3 to 4.0	V

^{*} The MPC857DSL does not contain SMC2 nor the Time Slot Assigner, and provides eight SDMA channels.

Table 2. Maximum Tolerated Ratings (Continued)

(GND = 0V)

Rating	Symbol	Value	Unit
Input voltage ²	V _{in}	GND-0.3 to VDDH	V
Temperature ³ (standard)	T _{A(min)}	0	°C
	T _{j(max)}	95	°C
Temperature ³ (extended)	T _{A(min)}	-40	°C
	T _{j(max)}	105	°C
Storage temperature range	T _{stg}	-55 to +150	°C

¹ The power supply of the device must start its ramp from 0.0 V.

Caution: All inputs cannot be more than 2.5 V greater than the supply voltage. This restriction applies to power-up and normal operation (that is, if the MPC857T is unpowered, voltage greater than 2.5 V must not be applied to its inputs).

This device contains circuitry protecting against damage due to high-static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{CC}).

Part IV Thermal Characteristics

Table 3 shows the thermal characteristics for the MPC857T.

Table 3. MPC857T Thermal Resistance Data

Rating	Envi	ronment	Symbol	Value	Unit
Junction to ambient ¹	Natural Convection	Single layer board (1s)	R _{JA} ²	40	°C/W
		Four layer board (2s2p)	R _{JMA} ³	25	
	Air flow (200 ft/min)	Single layer board (1s)	R _{JMA} ³	32	
		Four layer board (2s2p)	R _{JMA} ³	21	
Junction to board 4			R _{JB}	15	
Junction to case 5			R _{JC}	7	
Junction to package top 6	Natural Convection		JT	2	
	Air flow (200 ft/min)		JT	3	

Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

Functional operating conditions are provided with the DC electrical specifications in Table 5. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device.

Minimum temperatures are guaranteed as ambient temperature, T_A. Maximum temperatures are guaranteed as junction temperature, T_i.

² Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal.

³ Per JEDEC JESD51-6 with the board horizontal.

Power Dissipation

- Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature. For exposed pad packages where the pad would be expected to be soldered, junction to case thermal resistance is a simulated value from the junction to the exposed pad without contact resistance.
- Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

Part V Power Dissipation

Table 4 provides power dissipation information. The modes are 1:1, where CPU and bus speeds are equal, and 2:1 mode, where CPU frequency is twice bus speed.

Die Revision	Frequency	Typical ¹	Maximum ²	Unit
0	50 MHz	656	735	mW
(1:1 Mode)	66 MHz	TBD	TBD	mW
0	66 MHz	722	762	mW
(2:1 Mode)	80 MHz	851	909	mW

Table 4. Power Dissipation (P_D)

NOTE

Values in Table 4 represent VDDL based power dissipation and do not include I/O power dissipation over VDDH. I/O power dissipation varies widely by application due to buffer current, depending on external circuitry.

Part VI DC Characteristics

Table 5 provides the DC electrical characteristics for the MPC857T.

Table 5. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Uni t
Operating voltage at 40 MHz or less	VDDH, VDDL, VDDSYN	3.0	3.6	V
	KAPWR (power-down mode)	2.0	3.6	V
	KAPWR (all other operating modes)	VDDH - 0.4	VDDH	V
Operating voltage greater than 40 MHz	VDDH, VDDL, KAPWR, VDDSYN	3.135	3.465	V
	KAPWR (power-down mode)	2.0	3.6	V
	KAPWR (all other operating with modes) VDDH - 0.4		VDDH	V
Input High Voltage (all inputs except EXTAL and EXTCLK)	VIH	2.0	5.5	V

Typical power dissipation is measured at 3.3V.

² Maximum power dissipation is measured at 3.5V.

Table 5. DC Electrical Specifications (Continued)

Characteristic	Symbol	Min	Max	Uni t
Input Low Voltage	VIL	GND	0.8	V
EXTAL, EXTCLK Input High Voltage	VIHC	0.7*(VCC)	VCC+0.3	V
Input Leakage Current, Vin = 5.5V (Except TMS, TRST, DSCK and DSDI pins)	l _{in}	_	100	μΑ
Input Leakage Current, Vin = 3.6V (Except TMS, TRST, DSCK, and DSDI)	I _{In}	_	10	μΑ
Input Leakage Current, Vin = 0V (Except TMS, TRST, DSCK and DSDI pins)	I _{In}	_	10	μΑ
Input Capacitance 1	C _{in}	_	20	pF
Output High Voltage, IOH = -2.0 mA, VDDH = 3.0V Except XTAL, XFC, and Open drain pins	VOH	2.4	_	V
Output Low Voltage IOL = 2.0 mA (CLKOUT) IOL = 3.2 mA ² IOL = 5.3 mA ³ IOL = 7.0 mA (TXD1/PA14, PA12) IOL = 8.9 mA (TS, TA, TEA, BI, BB, HRESET, SRESET)	VOL	_	0.5	V

¹ Input capacitance is periodically sampled.

BDIP/GPL_B(5), BR, BG, FRZ/IRQ6, CS(0:5), CS(6)/CE(1)_B, CS(7)/CE(2)_B, WE0/BS_B0/IORD, WE1/BS_B1/IOWR, WE2/BS_B2/PCOE, WE3/BS_B3/PCWE, BS_A(0:3), GPL_A0/GPL_B0, OE/GPL_A1/GPL_B1, GPL_A(2:3)/GPL_B(2:3)/CS(2:3), UPWAITA/GPL_A4, UPWAITB/GPL_B4, GPL_A5, ALE_A, CE1_A, CE2_A, ALE_B/DSCK/AT1, OP(0:1), OP2/MODCK1/STS, OP3/MODCK2/DSDO, BADDR(28:30)

Part VII Thermal Calculation and Measurement

For the following discussions, P_D = (VDD x IDD) + PI/O, where PI/O is the power dissipation of the I/O drivers.

7.1 Estimation with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T_I, in °C can be obtained from the equation:

$$T_J = T_A + (R_{JA} \times P_D)$$

where:

A(0:31), TSIZO/REG, TSIZ1, D(0:31), DP(0:3)/IRQ(3:6), RD/WR, BURST, RSV/IRQ2, IP_B(0:1)/IWP(0:1)/VFLS(0:1), IP_B2/IOIS16_B/AT2, IP_B3/IWP2/VF2, IP_B4/LWP0/VF0, IP_B5/LWP1/VF1, IP_B6/DSDI/AT0, IP_B7/PTR/AT3, RXD1 /PA15, PA13, PA11, PA10, L1TXDA/PA9, L1RXDA/PA8, TIN1/L1RCLKA/BRGO1/CLK1/PA7, BRGCLK1/TOUT1/CLK2/PA6, TIN2/L1TCLKA/BRGO2/CLK3/PA5, TOUT2/CLK4/PA4, TIN3/BRGO3/CLK5/PA3, BRGCLK2/TOUT3/CLK6/PA2, TIN4/BRGO4/CLK7/PA1, TOUT4/CLK8/PA0, REJCT1/SPISEL/PB31, SPICLK/PB30, SPIMOSI/PB29, BRGO4/SPIMISO/PB28, BRGO1/I2CSDA/PB27, BRGO2/I2CSCL/PB26, SMTXD1/PB25, SMRXD1/PB24, SMSYN1/SDACK1/PB23, SMSYN2/SDACK2/PB22, SMTXD2/PB21, SMRXD2/L1CLKOA/PB20, L1ST1/RTS1/PB19, L1ST2/PB18, L1ST3/PB17, L1ST4/L1RQA/PB16, BRGO3/PB15, RSTRT1/PB14, L1ST1/RTS1/DREQ0/PC15, L1ST2/DREQ1/PC14, L1ST3/PC13, L1ST4/L1RQA/PC12, CTS1/PC11, TGATE1/CD1/PC10, PC9, TGATE2/PC8, SDACK2/PC7, PC6, SDACK1/L1TSYNCA/PC5, L1RSYNCA/PC4, PD15, PD14, PD13, PD12, PD11, PD10, PD9, PD8, PD5, PD6, PD7, PD4, PD3, MII_MDC, MII_TX_ER, MII_EN, MII_MDIO, MII_TXD[0:3]

Thermal Calculation and MeasurementEstimation with Junction-to-Case Thermal Resistance

 T_A = ambient temperature °C

R _{JA} = package junction-to-ambient thermal resistance (°C/W)

 P_D = power dissipation in package

The junction-to-ambient thermal resistance is an industry standard value which provides a quick and easy estimation of thermal performance. However, the answer is only an estimate; test cases have demonstrated that errors of a factor of two (in the quantity T_I - T_A) are possible.

7.2 Estimation with Junction-to-Case Thermal Resistance

Historically, the thermal resistance has frequently been expressed as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

$$R_{JA} = R_{JC} + R_{CA}$$

where:

R $_{JA}$ = junction-to-ambient thermal resistance ($^{\circ}$ C/W)

R _{JC} = junction-to-case thermal resistance (°C/W)

 R_{CA} = case-to-ambient thermal resistance (°C/W)

R _{JC} is device related and cannot be influenced by the user. The user adjusts the thermal environment to affect the case-to-ambient thermal resistance, R _{CA}. For instance, the user can change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This thermal model is most useful for ceramic packages with heat sinks where some 90% of the heat flows through the case and the heat sink to the ambient environment. For most packages, a better model is required.

7.3 Estimation with Junction-to-Board Thermal Resistance

A simple package thermal model which has demonstrated reasonable accuracy (about 20%) is a two resistor model consisting of a junction-to-board and a junction-to-case thermal resistance. The junction-to-case covers the situation where a heat sink is used or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. It has been observed that the thermal performance of most plastic packages and especially PBGA packages is strongly dependent on the board temperature; see Figure 3.

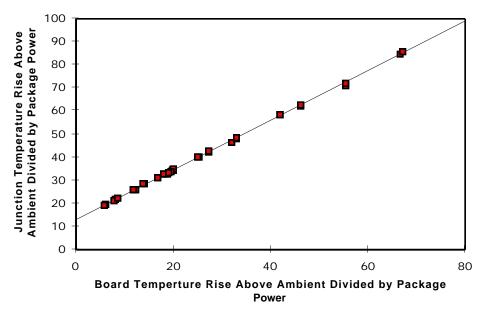


Figure 3. Effect of Board Temperature Rise on Thermal Behavior

If the board temperature is known, an estimate of the junction temperature in the environment can be made using the following equation:

$$T_J = T_B + (R_{JB} \times P_D)$$

where:

 $R_{JB} = \text{junction-to-board thermal resistance (°C/W)}$

 $T_{\rm R}$ = board temperature °C

 P_D = power dissipation in package

If the board temperature is known and the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. For this method to work, the board and board mounting must be similar to the test board used to determine the junction-to-board thermal resistance, namely a 2s2p (board with a power and a ground plane) and vias attaching the thermal balls to the ground plane.

7.4 Estimation Using Simulation

When the board temperature is not known, a thermal simulation of the application is needed. The simple two resistor model can be used with the thermal simulation of the application [2], or a more accurate and complex model of the package can be used in the thermal simulation.

7.5 Experimental Determination

To determine the junction temperature of the device in the application after prototypes are available, the thermal characterization parameter ($_{\rm JT}$) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + ($$
 $J_T \times P_D)$

where:

Layout Practices References

IT = thermal characterization parameter

 T_T = thermocouple temperature on top of package

 P_D = power dissipation in package

The thermal characterization parameter is measured per JESD51-2 specification published by JEDEC using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

7.6 References

Semiconductor Equipment and Materials International (415) 964-5111

805 East Middlefield Rd Mountain View, CA 94043

MIL-SPEC and EIA/JESD (JEDEC) specifications 800-854-7179 or (Available from Global Engineering Documents) 303-397-7956

JEDEC Specifications http://www.jedec.org

1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47-54.

2. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212-220.

Part VIII Layout Practices

Each V_{CC} pin on the MPC857T should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{CC} power supply should be bypassed to ground using at least four 0.1 μF by-pass capacitors located as close as possible to the four sides of the package. The capacitor leads and associated printed circuit traces connecting to chip V_{CC} and GND should be kept to less than half an inch per capacitor lead. A four-layer board is recommended, employing two inner layers as V_{CC} and GND planes.

All output pins on the MPC857T have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data busses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{CC} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins.

Part IX Bus Signal Timing

Table 6 provides the bus operation timing for the MPC857T at 33 MHz, 40 Mhz, 50 MHz and 66 Mhz.

The maximum bus speed supported by the MPC857T is 66 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC857T used at 80MHz must be configured for a 40 MHz bus).

The timing for the MPC857T bus shown assumes a 50-pF load for maximum delays and a 0-pF load for minimum delays.

Table 6. Bus Operation Timings

Mirror	Characteristic	33 1	ИНz	40 I	ИНz	50 I	ИНz	66 1	MHz	Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B1	CLKOUT period	30.30	30.30	25.00	30.30	20.00	30.30	15.15	30.30	ns
В1а	EXTCLK to CLKOUT phase skew (EXTCLK > 15 MHz and MF <= 2)	-0.90	0.90	-0.90	0.90	-0.90	0.90	-0.90	0.90	ns
B1b	EXTCLK to CLKOUT phase skew (EXTCLK > 10 MHz and MF < 10)	-2.30	2.30	-2.30	2.30	-2.30	2.30	-2.30	2.30	ns
B1c	CLKOUT phase jitter (EXTCLK > 15 MHz and MF <= 2) 1	-0.60	0.60	-0.60	0.60	-0.60	0.60	-0.60	0.60	ns
B1d	CLKOUT phase jitter ¹	-2.00	2.00	-2.00	2.00	-2.00	2.00	-2.00	2.00	ns
B1e	CLKOUT frequency jitter (MF < 10) ¹	_	0.50	_	0.50	_	0.50	_	0.50	%
B1f	CLKOUT frequency jitter (10 < MF < 500) ¹	_	2.00	_	2.00	_	2.00	_	2.00	%
B1g	CLKOUT frequency jitter (MF > 500) ¹		3.00	_	3.00	_	3.00	_	3.00	%
B1h	Frequency jitter on EXTCLK ²	_	0.50	_	0.50	_	0.50	_	0.50	%
B2	CLKOUT pulse width low	12.12	_	10.00	_	8.00	_	6.06	_	ns
В3	CLKOUT width high	12.12	_	10.00	_	8.00	_	6.06	_	ns
B4	CLKOUT rise time ³	_	4.00	_	4.00	_	4.00	_	4.00	ns
B5 ³³	CLKOUT fall time ³	_	4.00	_	4.00	_	4.00	_	4.00	ns
В7	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31), DP(0:3) invalid	7.58	-	6.25	_	5.00		3.80	_	ns
В7а	CLKOUT to TSIZ(0:1), REG, RSV, AT(0:3), BDIP, PTR invalid	7.58	_	6.25	_	5.00	_	3.80	_	ns
B7b	CLKOUT to BR, BG, FRZ, VFLS(0:1), VF(0:2) IWP(0:2), LWP(0:1), STS invalid ⁴	7.58	_	6.25	_	5.00	_	3.80	_	ns
B8	CLKOUT to A(0:31), BADDR(28:30) RD/WR, BURST, D(0:31), DP(0:3) valid	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B8a	CLKOUT to TSIZ(0:1), REG, RSV, AT(0:3) BDIP, PTR valid	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B8b	CLKOUT to BR, BG, VFLS(0:1), VF(0:2), IWP(0:2), FRZ, LWP(0:1), STS Valid ⁴	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
В9	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31), DP(0:3), TSIZ(0:1), REG, RSV, AT(0:3), PTR High-Z	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B11	CLKOUT to TS, BB assertion	7.58	13.58	6.25	12.25	5.00	11.00	3.80	11.29	ns

Bus Signal TimingReferences

Table 6. Bus Operation Timings (Continued)

Niver	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		l lm!t
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B11a	CLKOUT to TA, BI assertion (when driven by the memory controller or PCMCIA interface)	2.50	9.25	2.50	9.25	2.50	9.25	2.50	9.75	ns
B12	CLKOUT to TS, BB negation	7.58	14.33	6.25	13.00	5.00	11.75	3.80	8.54	ns
B12a	CLKOUT to TA, BI negation (when driven by the memory controller or PCMCIA interface)	2.50	11.00	2.50	11.00	2.50	11.00	2.50	9.00	ns
B13	CLKOUT to TS, BB High-Z	7.58	21.58	6.25	20.25	5.00	19.00	3.80	14.04	ns
B13a	CLKOUT to TA, BI High-Z (when driven by the memory controller or PCMCIA interface)	2.50	15.00	2.50	15.00	2.50	15.00	2.50	15.00	ns
B14	CLKOUT to TEA assertion	2.50	10.00	2.50	10.00	2.50	10.00	2.50	9.00	ns
B15	CLKOUT to TEA High-Z	2.50	15.00	2.50	15.00	2.50	15.00	2.50	15.00	ns
B16	TA, BI valid to CLKOUT (setup time)	9.75	_	9.75	_	9.75	_	6.00	_	ns
B16a	TEA, KR, RETRY, CR valid to CLKOUT (setup time)	10.00	_	10.00	_	10.00	_	4.50	_	ns
B16b	BB, BG, BR, valid to CLKOUT (setup time) 5	8.50	_	8.50	_	8.50	_	4.00	_	ns
B17	CLKOUT to TA, TEA, BI, BB, BG, BR valid (hold time).	1.00	_	1.00	_	1.00	_	2.00	_	ns
B17a	CLKOUT to KR, RETRY, CR valid (hold time)	2.00	_	2.00	_	2.00	_	2.00	_	ns
B18	D(0:31), DP(0:3) valid to CLKOUT rising edge (setup time) ⁶	6.00	_	6.00	_	6.00	_	6.00	_	ns
B19	CLKOUT rising edge to D(0:31), DP(0:3) valid (hold time) ⁶	1.00	_	1.00	_	1.00	_	2.00	_	ns
B20	D(0:31), DP(0:3) valid to CLKOUT falling edge (setup time) ⁷	4.00	_	4.00	_	4.00	_	4.00	_	ns
B21	CLKOUT falling edge to D(0:31), DP(0:3) valid (hold Time) ⁷	2.00	_	2.00	_	2.00	_	2.00	_	ns
B22	CLKOUT rising edge to \overline{CS} asserted GPCM ACS = 00	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B22a	CLKOUT falling edge to $\overline{\text{CS}}$ asserted GPCM ACS = 10, TRLX = 0	_	8.00	_	8.00	_	8.00	_	8.00	ns
B22b	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B22c	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 1	10.86	17.99	8.88	16.00	7.00	14.13	5.18	12.31	ns
B23	CLKOUT rising edge to CS negated GPCM read access, GPCM write access ACS = 00, TRLX = 0 & CSNT = 0	2.00	8.00	2.00	8.00	2.00	8.00	2.00	8.00	ns

Table 6. Bus Operation Timings (Continued)

Mum	Characteristic	33 I	ИНz	40 I	ИНz	50 MHz		66 MHz		Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B24	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 0.	5.58	_	4.25	_	3.00	_	1.79	_	ns
B24a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11 TRLX = 0	13.15	_	10.50	_	8.00	_	5.58	_	ns
B25	CLKOUT rising edge to $\overline{\text{OE}}$, $\overline{\text{WE}}$ (0:3) asserted		9.00		9.00		9.00		9.00	ns
B26	CLKOUT rising edge to OE negated	2.00	9.00	2.00	9.00	2.00	9.00	2.00	9.00	ns
B27	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 1	35.88	_	29.25	_	23.00	_	16.94	_	ns
B27a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11, TRLX = 1	43.45	_	35.50	_	28.00	_	20.73	_	ns
B28	CLKOUT rising edge to $\overline{WE}(0:3)$ negated GPCM write access CSNT = 0		9.00	_	9.00	_	9.00	_	9.00	ns
B28a	CLKOUT falling edge to $\overline{\text{WE}}(0:3)$ negated GPCM write access TRLX = 0, CSNT = 1, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B28b	CLKOUT falling edge to $\overline{\text{CS}}$ negated GPCM write access TRLX = 0, CSNT = 1 ACS = 10 or ACS = 11, EBDF = 0		14.33	_	13.00	_	11.75	_	10.54	ns
B28c	CLKOUT falling edge to $\overline{\text{WE}}(0:3)$ negated GPCM write access TRLX = 0, CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	10.86	17.99	8.88	16.00	7.00	14.13	5.18	12.31	ns
B28d	CLKOUT falling edge to $\overline{\text{CS}}$ negated GPCM write access TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1		17.99	_	16.00	_	14.13	_	12.31	ns
B29	WE(0:3) negated to D(0:31), DP(0:3) High-Z GPCM write access, CSNT = 0, EBDF = 0	5.58	_	4.25	_	3.00	_	1.79	_	ns
B29a	WE(0:3) negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, EBDF = 0	13.15	_	10.5	_	8.00	_	5.58	_	ns
B29b	CS negated to D(0:31), DP(0:3), High Z GPCM write access, ACS = 00, TRLX = 0 & CSNT = 0	5.58	_	4.25	_	3.00	_	1.79	_	ns
B29c	CS negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11 EBDF = 0	13.15	_	10.5	_	8.00	_	5.58	_	ns
B29d	$\overline{\text{WE}}$ (0:3) negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 0	43.45	_	35.5	_	28.00	_	20.73	_	ns
B29e	CS negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10, or ACS = 11 EBDF = 0	43.45	_	35.5	_	28.00	_	29.73	_	ns

Bus Signal TimingReferences

Table 6. Bus Operation Timings (Continued)

Nium	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B29f	WE(0:3) negated to D(0:31), DP(0:3) High Z GPCM write access, TRLX = 0, CSNT = 1, EBDF = 1	8.86	_	6.88	_	5.00		3.18	_	ns
B29g	CS negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1 ACS = 10 or ACS = 11, EBDF = 1	8.86	_	6.88	_	5.00	_	3.18	_	ns
B29h	WE(0:3) negated to D(0:31), DP(0:3) High Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 1	38.67	_	31.38	_	24.50	_	17.83	_	ns
B29i	CS negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	38.67	_	31.38	_	24.50	_	17.83	_	ns
B30	CS, WE(0:3) negated to A(0:31), BADDR(28:30) Invalid GPCM write access ⁸	5.58	_	4.25	_	3.00	_	1.79	_	ns
B30a	WE(0:3) negated to A(0:31), BADDR(28:30) Invalid GPCM, write access, TRLX = 0, CSNT = 1, CS negated to A(0:31) invalid GPCM write access TRLX = 0, CSNT = 1 ACS = 10, or ACS == 11, EBDF = 0	13.15	_	10.50	_	8.00	_	5.58	_	ns
B30b	WE(0:3) negated to A(0:31) Invalid GPCM BADDR(28:30) invalid GPCM write access, TRLX = 1, CSNT = 1. CS negated to A(0:31) Invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10, or ACS == 11 EBDF = 0	43.45	_	35.50	_	28.00	_	20.73	_	ns
B30c	WE(0:3) negated to A(0:31), BADDR(28:30) invalid GPCM write access, TRLX = 0, CSNT = 1. CS negated to A(0:31) invalid GPCM write access, TRLX = 0, CSNT = 1 ACS = 10, ACS == 11, EBDF = 1	8.36	_	6.38	_	4.50	_	2.68	_	ns
B30d	WE(0:3) negated to A(0:31), BADDR(28:30) invalid GPCM write access TRLX = 1, CSNT =1, CS negated to A(0:31) invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10 or 11, EBDF = 1	38.67	_	31.38	_	24.50	_	17.83	_	ns
B31	CLKOUT falling edge to $\overline{\text{CS}}$ valid - as requested by control bit CST4 in the corresponding word in the UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B31a	CLKOUT falling edge to CS valid - as requested by control bit CST1 in the corresponding word in the UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns

Table 6. Bus Operation Timings (Continued)

Num	Characteristic	33 I	MHz	40 [ИНz	50 MHz		66 MHz		Unit
Num		Min	Max	Min	Max	Min	Max	Min	Max	Unit
B31b	CLKOUT rising edge to CS valid - as requested by control bit CST2 in the corresponding word in the UPM	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B31c	CLKOUT rising edge to CS valid- as requested by control bit CST3 in the corresponding word in the UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B31d	CLKOUT falling edge to \overline{CS} valid, as requested by control bit CST1 in the corresponding word in the UPM EBDF = 1	13.26	17.99	11.28	16.00	9.40	14.13	7.58	12.31	ns
B32	CLKOUT falling edge to BS valid- as requested by control bit BST4 in the corresponding word in the UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B32a	CLKOUT falling edge to BS valid - as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B32b	CLKOUT rising edge to BS valid - as requested by control bit BST2 in the corresponding word in the UPM	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B32c	CLKOUT rising edge to BS valid - as requested by control bit BST3 in the corresponding word in the UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B32d	CLKOUT falling edge to BS valid- as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 1	13.26	17.99	11.28	16.00	9.40	14.13	7.58	12.31	ns
B33	CLKOUT falling edge to GPL valid - as requested by control bit GxT4 in the corresponding word in the UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B33a	CLKOUT rising edge to GPL Valid - as requested by control bit GxT3 in the corresponding word in the UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B34	A(0:31), BADDR(28:30), and D(0:31) to CS valid - as requested by control bit CST4 in the corresponding word in the UPM	5.58	_	4.25	_	3.00	_	1.79	_	ns
B34a	A(0:31), BADDR(28:30), and D(0:31) to CS valid - as requested by control bit CST1 in the corresponding word in the UPM	13.15	_	10.50	_	8.00	_	5.58	_	ns
B34b	A(0:31), BADDR(28:30), and D(0:31) to CS valid - as requested by CST2 in the corresponding word in UPM	20.73	_	16.75	_	13.00	_	9.36	_	ns

Table 6. Bus Operation Timings (Continued)

Num	Characteristic	33 I	ИНz	40 MHz		50 MHz		66 MHz		Unit
Nulli		Min	Max	Min	Max	Min	Max	Min	Max	Onne
B35	A(0:31), BADDR(28:30) to \overline{CS} valid - as requested by control bit BST4 in the corresponding word in the UPM	5.58	_	4.25	_	3.00	_	1.79	_	ns
B35a	A(0:31), BADDR(28:30), and D(0:31) to BS valid - As Requested by BST1 in the corresponding word in the UPM	13.15	_	10.50	_	8.00	_	5.58	_	ns
B35b	A(0:31), BADDR(28:30), and D(0:31) to BS valid - as requested by control bit BST2 in the corresponding word in the UPM	20.73	_	16.75	_	13.00	_	9.36	_	ns
B36	A(0:31), BADDR(28:30), and D(0:31) to GPL valid as requested by control bit GxT4 in the corresponding word in the UPM	5.58	_	4.25	_	3.00	_	1.79	_	ns
B37	UPWAIT valid to CLKOUT falling edge 9	6.00	_	6.00	_	6.00	_	6.00	_	ns
B38	CLKOUT falling edge to UPWAIT valid 9	1.00	_	1.00	_	1.00	_	1.00	_	ns
B39	AS valid to CLKOUT rising edge 10	7.00	_	7.00	_	7.00	_	7.00	_	ns
B40	A(0:31), TSIZ(0:1), RD/WR, BURST, valid to CLKOUT rising edge	7.00	_	7.00	_	7.00	_	7.00	_	ns
B41	TS valid to CLKOUT rising edge (setup time)	7.00	_	7.00	_	7.00	_	7.00	_	ns
B42	CLKOUT rising edge to TS valid (hold time)	2.00	_	2.00	_	2.00	_	2.00	_	ns
B43	AS negation to memory controller signals negation	_	TBD	_	TBD	_	TBD	_	TBD	ns

Phase and frequency jitter performance results are only valid if the input jitter is less than the prescribed value.

² If the rate of change of the frequency of EXTAL is slow (I.e. it does not jump between the minimum and maximum values in one cycle) or the frequency of the jitter is fast (I.e., it does not stay at an extreme value for a long time) then the maximum allowed jitter on EXTAL can be up to 2%.

³ The timings specified in B4 and B5 are based on full strength clock.

The timing for BR output is relevant when the MPC857T is selected to work with external bus arbiter. The timing for BG output is relevant when the MPC857T is selected to work with internal bus arbiter.

⁵ The timing required for \overline{BR} input is relevant when the MPC857T is selected to work with internal bus arbiter. The timing for \overline{BG} input is relevant when the MPC857T is selected to work with external bus arbiter.

⁶ The D(0:31) and DP(0:3) input timings B18 and B19 refer to the rising edge of the CLKOUT in which the TA input signal is asserted.

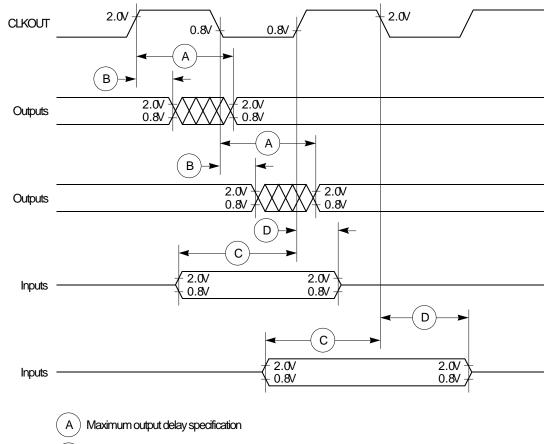
⁷ The D(0:31) and DP(0:3) input timings B20 and B21 refer to the falling edge of the CLKOUT. This timing is valid only for read accesses controlled by chip-selects under control of the UPM in the memory controller, for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

⁸ The timing B30 refers to $\overline{\text{CS}}$ when ACS = 00 and to $\overline{\text{WE}}$ (0:3) when CSNT = 0.

The signal UPWAIT is considered asynchronous to the CLKOUT and synchronized internally. The timings specified in B37 and B38 are specified to enable the freeze of the UPM output signals as described in Figure 19.

¹⁰ The $\overline{\text{AS}}$ signal is considered asynchronous to the CLKOUT. The timing B39 is specified in order to allow the behavior specified in Figure 22.

Figure 4 is the control timing diagram.



- (B) Minimum output hold time
- C Minimum input setup time specification
- D Minimum input hold time specification

Figure 4. Control Timing

Figure 5 provides the timing for the external clock.

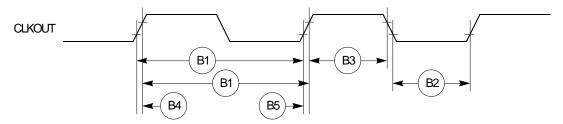


Figure 5. External Clock Timing

Figure 6 provides the timing for the synchronous output signals.

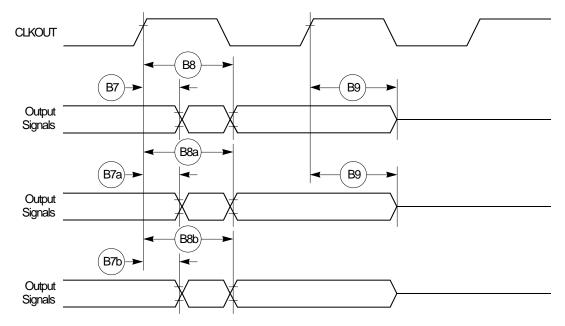


Figure 6. Synchronous Output Signals Timing

Figure 7 provides the timing for the synchronous active pull-up and open-drain output signals.

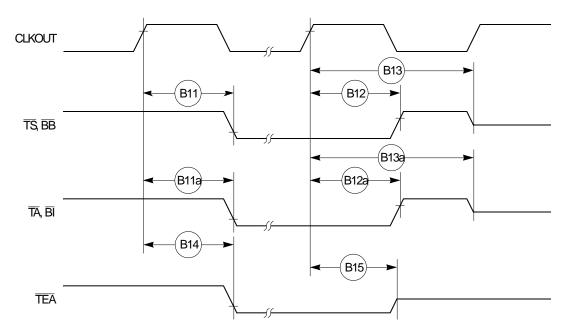


Figure 7. Synchronous Active Pull-Up Resistor and Open-Drain Outputs Signals Timing

Figure 8 provides the timing for the synchronous input signals.

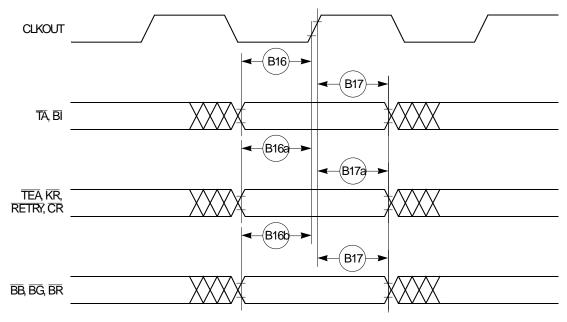


Figure 8. Synchronous Input Signals Timing

Figure 9 provides normal case timing for input data. It also applies to normal read accesses under the control of the UPM in the memory controller.

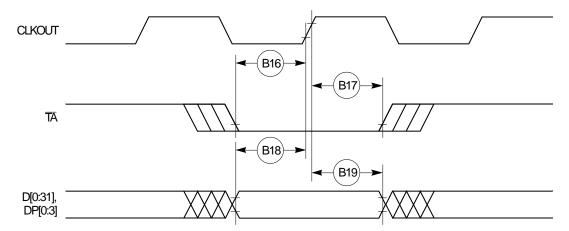


Figure 9. Input Data Timing in Normal Case

Figure 10 provides the timing for the input data controlled by the UPM for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

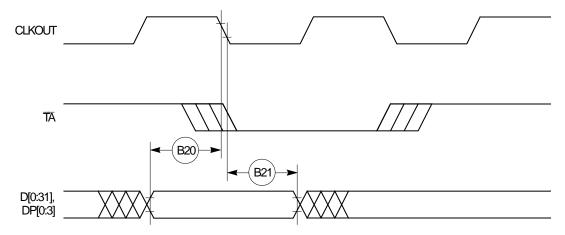


Figure 10. Input Data Timing when Controlled by UPM in the Memory Controller and DLT3 = 1

Figure 11 through Figure 14 provide the timing for the external bus read controlled by various GPCM factors.

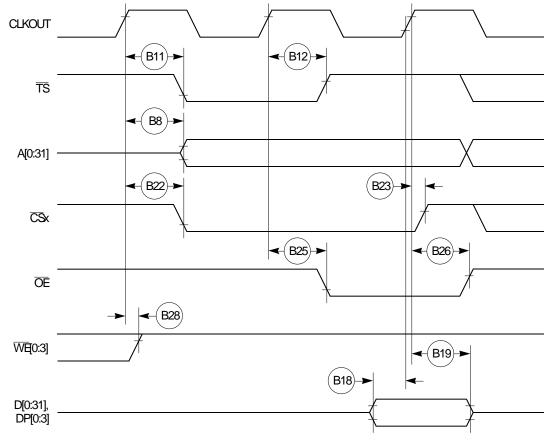


Figure 11. External Bus Read Timing (GPCM Controlled—ACS = 00)

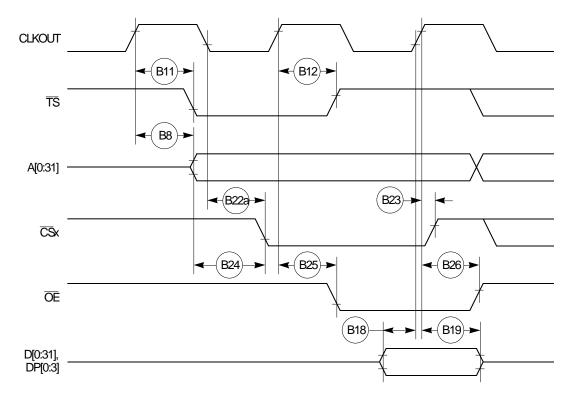


Figure 12. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 10)

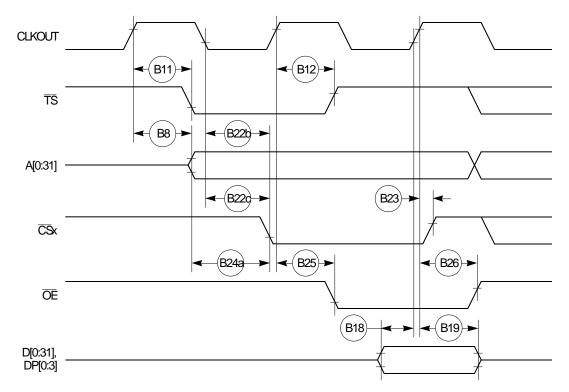


Figure 13. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 11)

Bus Signal TimingReferences

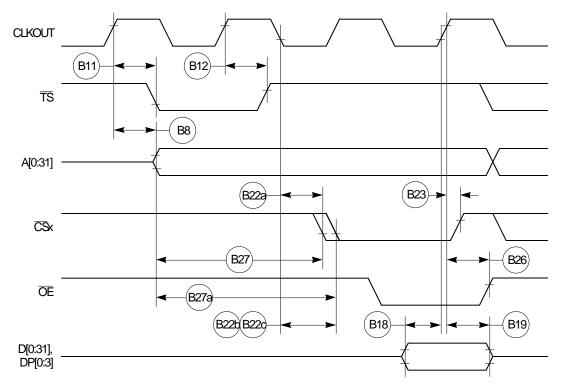


Figure 14. External Bus Read Timing (GPCM Controlled—TRLX = 1, ACS = 10, ACS = 11)

Figure 15 through Figure 17 provide the timing for the external bus write controlled by various GPCM factors.

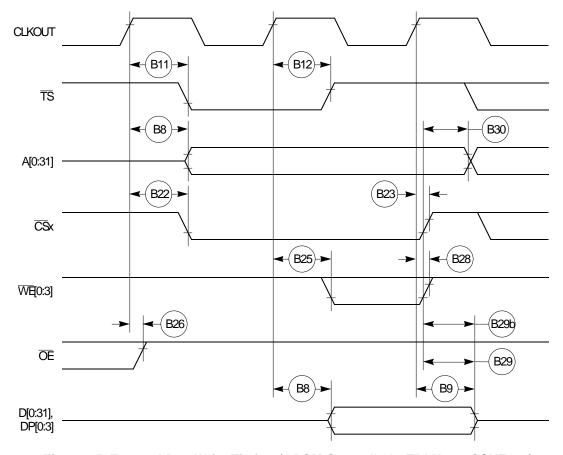


Figure 15. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 0)

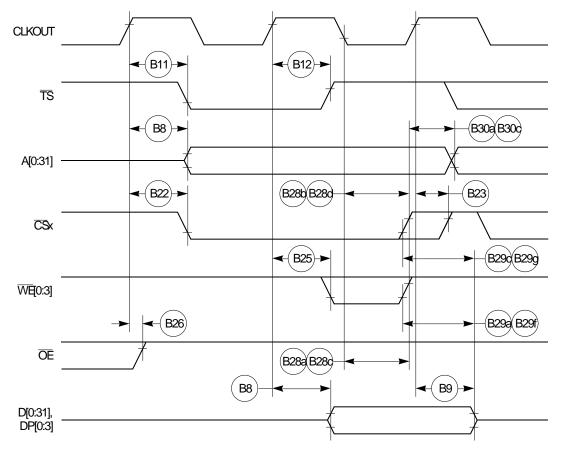


Figure 16. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 1)

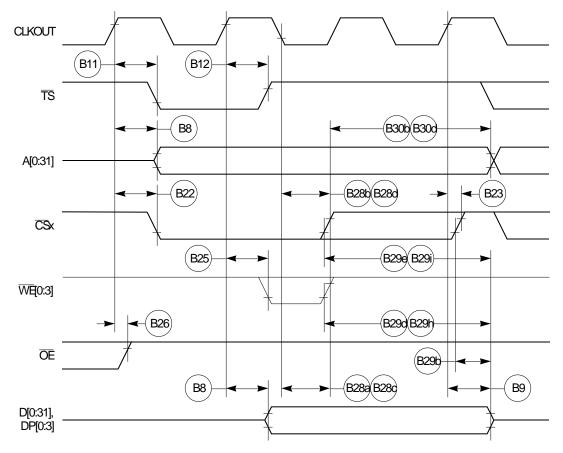


Figure 17. External Bus Write Timing (GPCM Controlled—TRLX = 1, CSNT = 1)

Figure 18 provides the timing for the external bus controlled by the UPM.

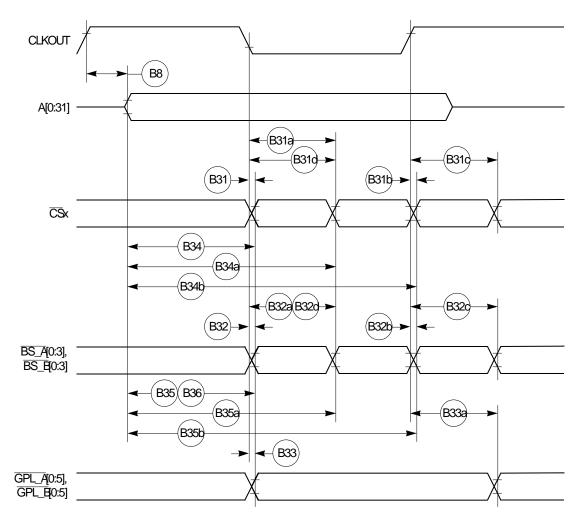


Figure 18. External Bus Timing (UPM Controlled Signals)

Figure 19 provides the timing for the asynchronous asserted UPWAIT signal controlled by the UPM.

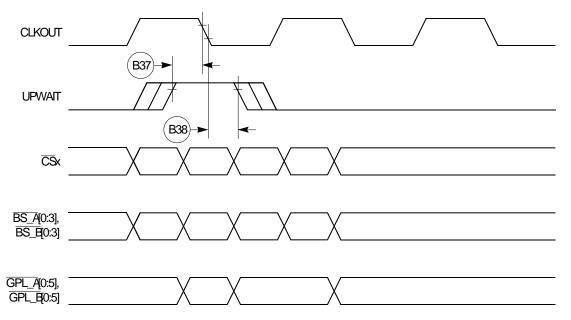


Figure 19. Asynchronous UPWAIT Asserted Detection in UPM Handled Cycles Timing

Figure 20 provides the timing for the asynchronous negated UPWAIT signal controlled by the UPM.

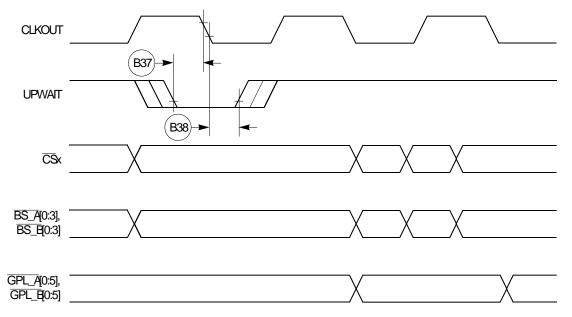


Figure 20. Asynchronous UPWAIT Negated Detection in UPM Handled Cycles Timing

Figure 21 provides the timing for the synchronous external master access controlled by the GPCM.

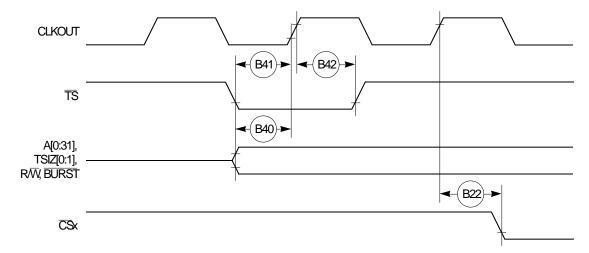


Figure 21. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 22 provides the timing for the asynchronous external master memory access controlled by the GPCM.

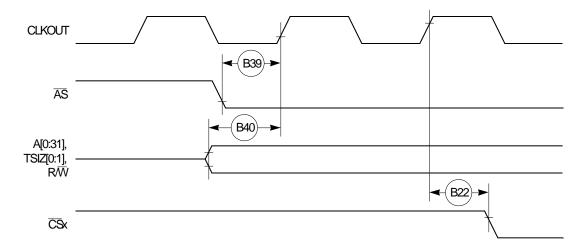


Figure 22. Asynchronous External Master Memory Access Timing (GPCM Controlled—ACS = 00)

Figure 23 provides the timing for the asynchronous external master control signals negation.

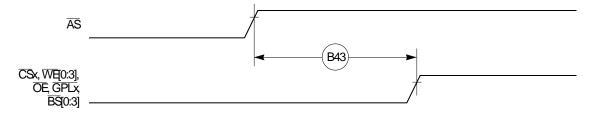


Figure 23. Asynchronous External Master—Control Signals Negation Timing

Table 7 provides interrupt timing for the MPC857T.

Table 7. Interrupt Timing

Num	Characteristic ¹	All Frequenc	Unit	
Nulli	Gilai acteristic	Min		
139	IRQx valid to CLKOUT rising edge (set up time)	6.00		ns
140	IRQx hold time after CLKOUT	2.00		ns
I41	IRQx pulse width low	3.00		ns
142	IRQx pulse width high	3.00		ns
143	IRQx edge-to-edge time	4xT _{CLOCKOUT}		_

The timings I39 and I40 describe the testing conditions under which the \overline{IRQ} lines are tested when being defined as level sensitive. The \overline{IRQ} lines are synchronized internally and do not have to be asserted or negated with reference to the CLKOUT.

The timings I41, I42, and I43 are specified to allow the correct function of the $\overline{\text{IRQ}}$ lines detection circuitry, and has no direct relation with the total system interrupt latency that the MPC857T is able to support.

Figure 24 provides the interrupt detection timing for the external level-sensitive lines.

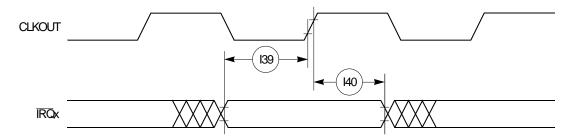


Figure 24. Interrupt Detection Timing for External Level Sensitive Lines

Figure 25 provides the interrupt detection timing for the external edge-sensitive lines.

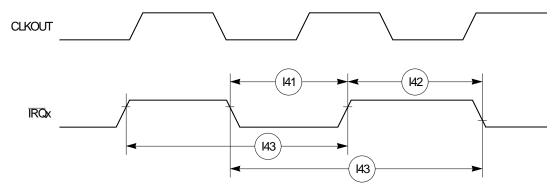


Figure 25. Interrupt Detection Timing for External Edge Sensitive Lines

Bus Signal TimingReferences

Table 8 shows the PCMCIA timing for the MPC857T.

Table 8. PCMCIA Timing

Num	Characteristic	33	MHz	40 MHz		50 MHz		66 MHz		Unit
Nulli		Min	Max	Min	Max	Min	Max	Min	Max	Onne
P44	A(0:31), REG valid to PCMCIA Strobe asserted. 1	20.73	_	16.75	_	13.00	_	9.36	_	ns
P45	A(0:31), REG valid to ALE negation. ¹	28.30	_	23.00	_	18.00	_	13.15	_	ns
P46	CLKOUT to REG valid	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P47	CLKOUT to REG Invalid.	8.58	_	7.25	_	6.00	_	4.84	_	ns
P48	CLKOUT to CE1, CE2 asserted.	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P49	CLKOUT to CE1, CE2 negated.	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P50	CLKOUT to PCOE, IORD, PCWE, IOWR assert time.	_	11.00	_	11.00	_	11.00	_	11.00	ns
P51	CLKOUT to PCOE, IORD, PCWE, IOWR negate time.	2.00	11.00	2.00	11.00	2.00	11.00	2.00	11.00	ns
P52	CLKOUT to ALE assert time	7.58	15.58	6.25	14.25	5.00	13.00	3.79	10.04	ns
P53	CLKOUT to ALE negate time	_	15.58	_	14.25	_	13.00	_	11.84	ns
P54	PCWE, IOWR negated to D(0:31) invalid.1	5.58	_	4.25	_	3.00	_	1.79	_	ns
P55	WAITA and WAITB valid to CLKOUT rising edge. ¹	8.00	_	8.00	_	8.00	_	8.00	_	ns
P56	CLKOUT rising edge to WAITA and WAITB invalid.1	2.00	_	2.00	_	2.00	_	2.00	_	ns

PSST = 1. Otherwise add PSST times cycle time.

These synchronous timings define when the $\overline{\text{WAITx}}$ signals are detected in order to freeze (or relieve) the PCMCIA current cycle. The $\overline{\text{WAITx}}$ assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See PCMCIA Interface in the MPC857T PowerQUICC User's Manual.

Figure 26 provides the PCMCIA access cycle timing for the external bus read.

PSHT = 0. Otherwise add PSHT times cycle time.

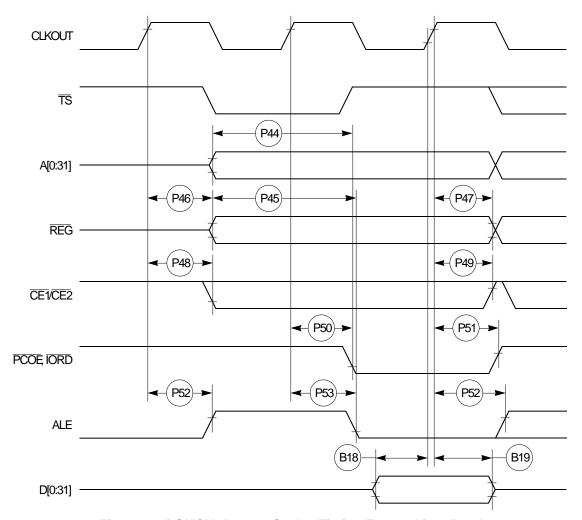


Figure 26. PCMCIA Access Cycles Timing External Bus Read

Figure 27 provides the PCMCIA access cycle timing for the external bus write.

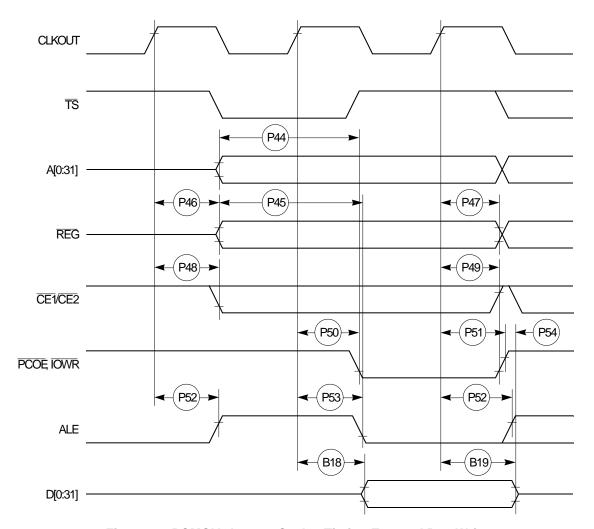


Figure 27. PCMCIA Access Cycles Timing External Bus Write

Figure 28 provides the PCMCIA WAIT signals detection timing.

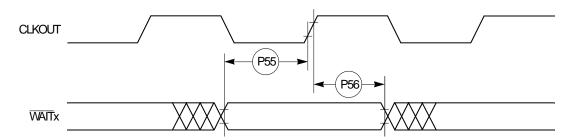


Figure 28. PCMCIA WAIT Signals Detection Timing

Table 9 shows the PCMCIA port timing for the MPC857T.

Table 9. PCMCIA Port Timing

Num	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	Oill
P57	CLKOUT to OPx Valid	_	19.00	_	19.00	_	19.00	_	19.00	ns
P58	HRESET negated to OPx drive ¹	25.73	_	21.75	_	18.00	_	14.36	_	ns
P59	IP_Xx valid to CLKOUT rising edge	5.00	_	5.00	_	5.00	_	5.00	_	ns
P60	CLKOUT rising edge to IP_Xx invalid	1.00	_	1.00	_	1.00	_	1.00	_	ns

¹ OP2 and OP3 only.

Figure 29 provides the PCMCIA output port timing for the MPC857T.

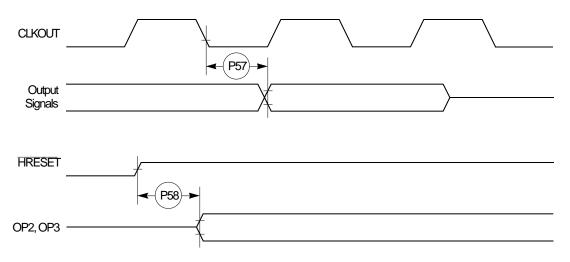


Figure 29. PCMCIA Output Port Timing

Figure 30 provides the PCMCIA output port timing for the MPC857T.

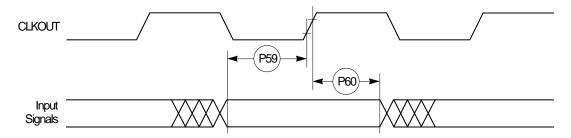


Figure 30. PCMCIA Input Port Timing

Table 10 shows the debug port timing for the MPC857T.

Table 10. Debug Port Timing

Num	Characteristic	All Frequence	All Frequencies				
Nulli	Characteristic	Min	Max	Unit			
D61	DSCK cycle time	3xT _{CLOCKOUT}		-			
D62	DSCK clock pulse width	1.25xT _{CLOCKOUT}		-			
D63	DSCK rise and fall times	0.00	3.00	ns			
D64	DSDI input data setup time	8.00		ns			
D65	DSDI data hold time	5.00		ns			
D66	DSCK low to DSDO data valid	0.00	15.00	ns			
D67	DSCK low to DSDO invalid	0.00	2.00	ns			

Figure 31 provides the input timing for the debug port clock.

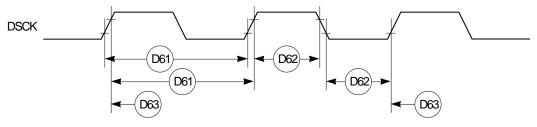


Figure 31. Debug Port Clock Input Timing

Figure 32 provides the timing for the debug port.

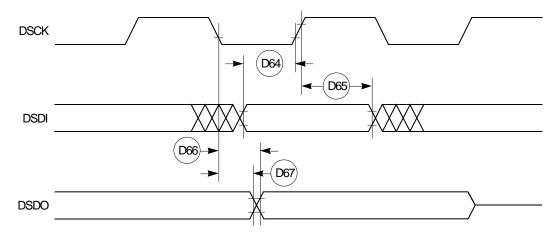


Figure 32. Debug Port Timings

Table 11 shows the reset timing for the MPC857T.

Table 11. Reset Timing

Num	Characteristic	33 N	ИHz	40 N	ИHz	50 N	ИHz	66 N	ИHz	Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
R69	CLKOUT to HRESET high impedance	_	20.00	_	20.00	_	20.00	_	20.00	ns
R70	CLKOUT to SRESET high impedance	_	20.00	_	20.00	_	20.00	_	20.00	ns
R71	RSTCONF pulse width	515.15	—	425.00	_	340.00	_	257.58	_	ns
R72	_	_	_	_	_	_	_	_	_	_
R73	Configuration data to HRESET rising edge set up time	504.55	_	425.00	_	350.00	_	277.27	_	ns
R74	Configuration data to RSTCONF rising edge set up time	350.00	_	350.00	_	350.00	_	350.00	_	ns
R75	Configuration data hold time after RSTCONF negation	0.00	_	0.00	_	0.00	_	0.00	_	ns
R76	Configuration data hold time after HRESET negation	0.00	_	0.00	_	0.00	_	0.00	_	ns
R77	HRESET and RSTCONF asserted to data out drive	_	25.00	_	25.00	_	25.00	_	25.00	ns
R78	RSTCONF negated to data out high impedance.	_	25.00	_	25.00	_	25.00	_	25.00	ns
R79	CLKOUT of last rising edge before chip three-states HRESET to data out high impedance.	_	25.00	_	25.00	_	25.00	_	25.00	ns
R80	DSDI, DSCK set up	90.91	_	75.00	_	60.00	_	45.45	_	ns
R81	DSDI, DSCK hold time	0.00	_	0.00	_	0.00	_	0.00	_	ns
R82	SRESET negated to CLKOUT rising edge for DSDI and DSCK sample	242.42	_	200.00	_	160.00	_	121.21	_	ns

Figure 33 shows the reset timing for the data bus configuration.

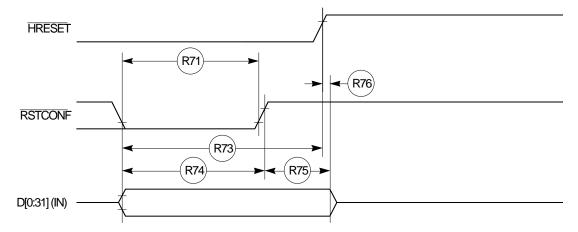


Figure 33. Reset Timing—Configuration from Data Bus

IEEE 1149.1 Electrical SpecificationsReferences

Figure 34 provides the reset timing for the data bus weak drive during configuration.

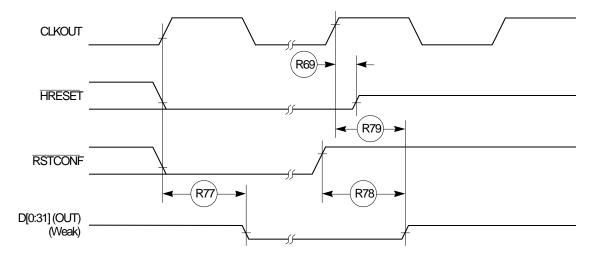


Figure 34. Reset Timing—Data Bus Weak Drive during Configuration

Figure 35 provides the reset timing for the debug port configuration.

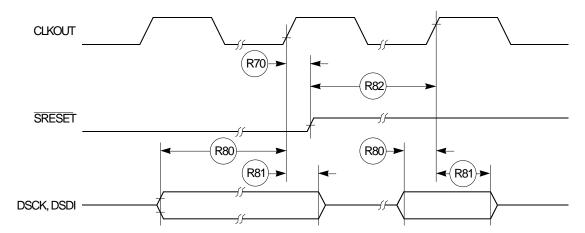


Figure 35. Reset Timing—Debug Port Configuration

Part X IEEE 1149.1 Electrical Specifications

Table 12 provides the JTAG timings for the MPC857T shown in Figure 36 to Figure 39. **Table 12. JTAG Timing**

Num	Characteristic	All Frequencies Min Max		Unit
	Gilaracteristic			Onne
J82	TCK cycle time	100.00	_	ns
J83	TCK clock pulse width measured at 1.5 V	40.00	_	ns
J84	TCK rise and fall times	0.00	10.00	ns
J85	TMS, TDI data setup time	5.00	_	ns
J86	TMS, TDI data hold time	25.00	_	ns

Table 12. JTAG Timing (Continued)

Num	Characteristic		All Frequencies	
Italii	Gridi de Contraction	Min	Unit	
J87	TCK low to TDO data valid	_	27.00	ns
J88	TCK low to TDO data invalid	0.00	_	ns
J89	TCK low to TDO high impedance	_	20.00	ns
J90	TRST assert time	100.00	_	ns
J91	TRST setup time to TCK low	40.00	_	ns
J92	TCK falling edge to output valid	_	50.00	ns
J93	TCK falling edge to output valid out of high impedance	_	50.00	ns
J94	TCK falling edge to output high impedance	_	50.00	ns
J95	Boundary scan input valid to TCK rising edge	50.00	_	ns
J96	TCK rising edge to boundary scan input invalid	50.00	_	ns

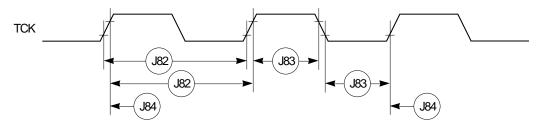


Figure 36. JTAG Test Clock Input Timing

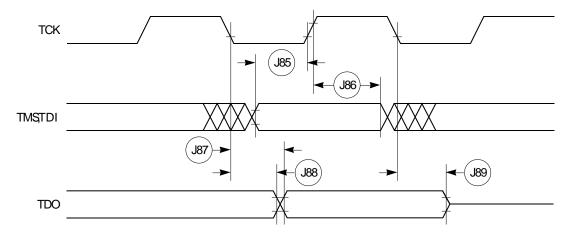


Figure 37. JTAG Test Access Port Timing Diagram

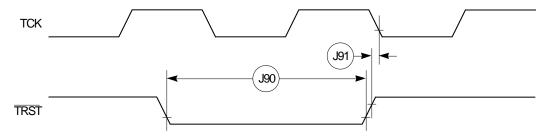


Figure 38. JTAG TRST Timing Diagram

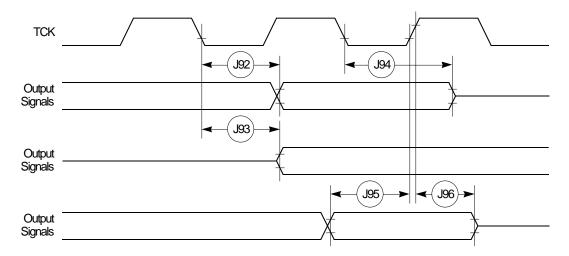


Figure 39. Boundary Scan (JTAG) Timing Diagram

Part XI CPM Electrical Characteristics

This section provides the AC and DC electrical specifications for the communications processor module (CPM) of the MPC857T.

11.1 PIP/PIO AC Electrical Specifications

Table 13 provides the PIP/PIO AC timings as shown in Figure 40 to Figure 44.

Table 13. PIP/PIO Timing

Num	Characteristic	All Frequencies		Unit
	Gilal acteristic	Min Max		
21	Data-in setup time to STBI low	0	_	ns
22	Data-In hold time to STBI high	2.5 – t3 ¹	_	clk
23	STBI pulse width	1.5	_	clk
24	STBO pulse width	1 clk – 5ns	_	ns
25	Data-out setup time to STBO low	2	_	clk
26	Data-out hold time from STBO high	5	_	clk

CPM Electrical CharacteristicsPIP/PIO AC Electrical Specifications

Table 13. PIP/PIO Timing (Continued)

Num	Characteristic	All Frequencies		Unit
Num	Characteristic	Min	Ollit	
27	STBI low to STBO low (Rx interlock)	_	2	clk
28	STBI low to STBO high (Tx interlock)	2		clk
29	Data-in setup time to clock high	15	_	ns
30	Data-in hold time from clock high	7.5	_	ns
31	Clock low to data-out valid (CPU writes data, control, or direction)	_	25	ns

¹ t3 = Specification 23

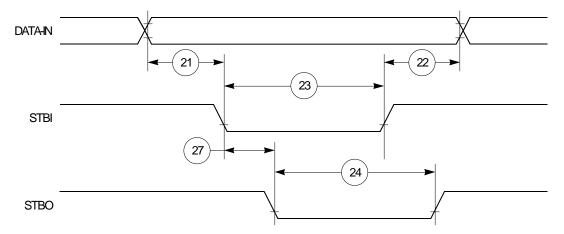


Figure 40. PIP Rx (Interlock Mode) Timing Diagram

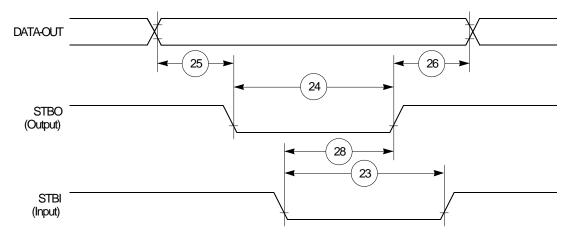


Figure 41. PIP Tx (Interlock Mode) Timing Diagram

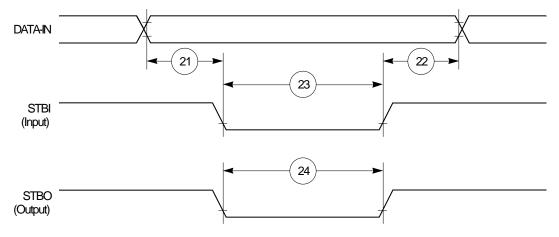


Figure 42. PIP Rx (Pulse Mode) Timing Diagram

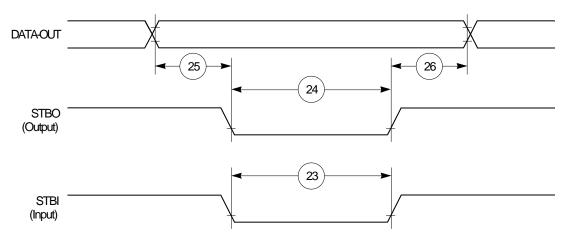


Figure 43. PIP TX (Pulse Mode) Timing Diagram

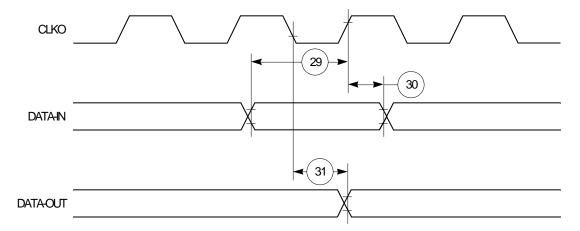


Figure 44. Parallel I/O Data-In/Data-Out Timing Diagram

11.2 Port C Interrupt AC Electrical Specifications

Table 14 provides the timings for port C interrupts.

Table 14. Port C Interrupt Timing

Num	Characteristic	33.34 MHz Min Max		Unit
	Gharacteristic			
35	Port C interrupt pulse width low (edge-triggered mode)	55	_	ns
36	Port C interrupt minimum time between active edges	55	_	ns

Figure 45 shows the port C interrupt detection timing.

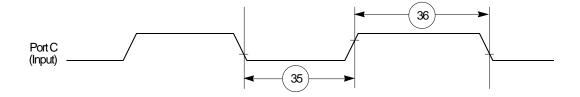


Figure 45. Port C Interrupt Detection Timing

11.3 IDMA Controller AC Electrical Specifications

Table 15 provides the IDMA controller timings as shown in Figure 46 to Figure 49.

Table 15. IDMA Controller Timing

Num	Characteristic	All Frequencies		Unit	
Num	Gilaracteristic	Min			
40	DREQ setup time to clock high	7	_	ns	
41	DREQ hold time from clock high	3	_	ns	
42	SDACK assertion delay from clock high	_	12	ns	
43	SDACK negation delay from clock low	_	12	ns	
44	SDACK negation delay from TA low	_	20	ns	
45	SDACK negation delay from clock high	_	15	ns	
46	TA assertion to falling edge of the clock setup time (applies to external TA)	7	_	ns	

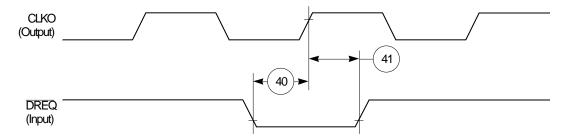


Figure 46. IDMA External Requests Timing Diagram

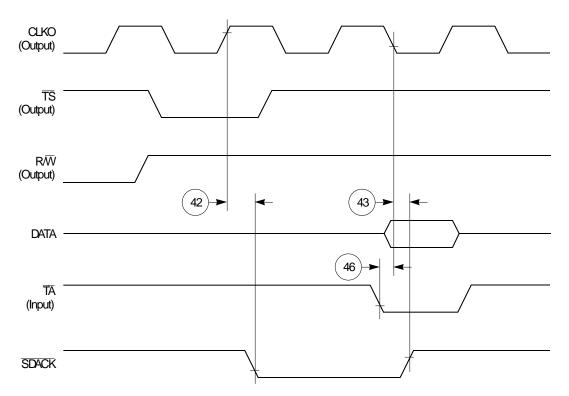


Figure 47. SDACK Timing Diagram—Peripheral Write, Externally-Generated TA

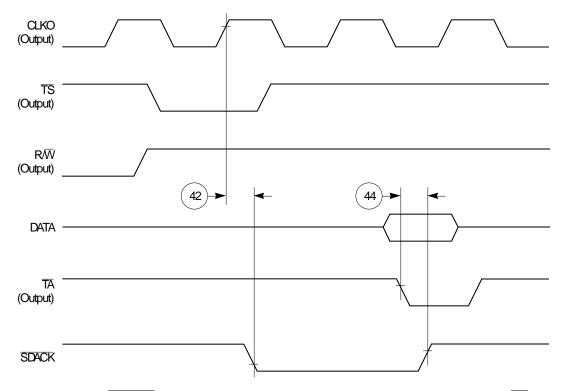


Figure 48. SDACK Timing Diagram—Peripheral Write, Internally-Generated TA

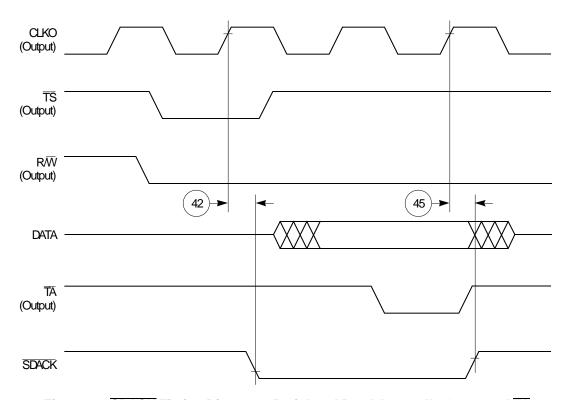


Figure 49. SDACK Timing Diagram—Peripheral Read, Internally-Generated TA

11.4 Baud Rate Generator AC Electrical Specifications

Table 16 provides the baud rate generator timings as shown in Figure 50.

Table 16. Baud Rate Generator Timing

Num	Characteristic	All Frequ	Unit	
Nulli	Characteristic	Min Max		
50	BRGO rise and fall time	_	10	ns
51	BRGO duty cycle	40	60	%
52	BRGO cycle	40	_	ns

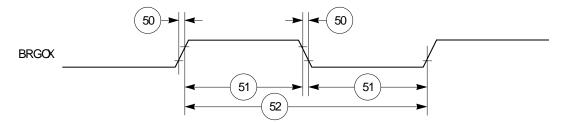


Figure 50. Baud Rate Generator Timing Diagram

11.5 Timer AC Electrical Specifications

Table 17 provides the general-purpose timer timings as shown in Figure 51.

Table 17. Timer Timing

Num	Characteristic	All Frequ	Unit		
Num	Characteristic	Min Max			
61	TIN/TGATE rise and fall time	10	_	ns	
62	TIN/TGATE low time	1	_	clk	
63	TIN/TGATE high time	2	_	clk	
64	TIN/TGATE cycle time	3	_	clk	
65	CLKO low to TOUT valid	3	25	ns	

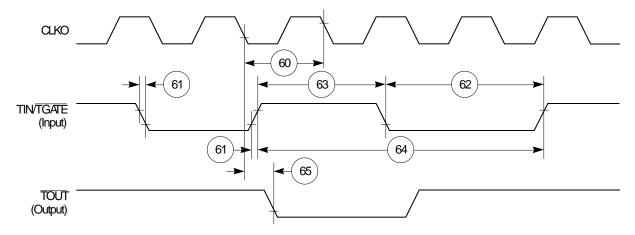


Figure 51. CPM General-Purpose Timers Timing Diagram

11.6 Serial Interface AC Electrical Specifications

Table 18 provides the serial interface timings as shown in Figure 52 to Figure 56.

Table 18. SI Timing

Num	Characteristic	A	Unit	
Nulli	Cital acteristic	Min	Max	
70	L1RCLK, L1TCLK frequency (DSC = 0) 1, 2	_	SYNCCLK/2.5	MHz
71	L1RCLK, L1TCLK width low (DSC = 0) ²	P + 10	_	ns
71a	L1RCLK, L1TCLK width high (DSC = 0) ³	P + 10	_	ns
72	L1TXD, L1ST(1-4), L1RQ, L1CLKO rise/fall time	_	15.00	ns
73	L1RSYNC, L1TSYNC valid to L1CLK edge (SYNC setup time)	20.00	_	ns
74	L1CLK edge to L1RSYNC, L1TSYNC, invalid (SYNC hold time)	35.00	_	ns
75	L1RSYNC, L1TSYNC rise/fall time	_	15.00	ns
76	L1RXD valid to L1CLK edge (L1RXD setup time)	17.00	_	ns
77	L1CLK edge to L1RXD invalid (L1RXD hold time)	13.00	_	ns
78	L1CLK edge to L1ST(1-4) valid ⁴	10.00	45.00	ns
78A	L1SYNC valid to L1ST(1-4) valid	10.00	45.00	ns
79	L1CLK edge to L1ST(1-4) invalid	10.00	45.00	ns
80	L1CLK edge to L1TXD valid	10.00	55.00	ns
80A	L1TSYNC valid to L1TXD valid ⁴	10.00	55.00	ns
81	L1CLK edge to L1TXD high impedance	0.00	42.00	ns
82	L1RCLK, L1TCLK frequency (DSC =1)	_	16.00 or SYNCCLK/2	MHz
83	L1RCLK, L1TCLK width low (DSC =1)	P + 10	_	ns
83a	L1RCLK, L1TCLK width high (DSC = 1) ³	P + 10	_	ns

CPM Electrical CharacteristicsSerial Interface AC Electrical Specifications

Table 18. SI Timing (Continued)

Num	Characteristic	Al	Unit	
	Characteristic	Min	Max	- Ollit
84	L1CLK edge to L1CLKO valid (DSC = 1)	_	30.00	ns
85	L1RQ valid before falling edge of L1TSYNC ⁴	1.00	_	L1TCLK
86	L1GR setup time ²	42.00	_	ns
87	L1GR hold time	42.00	_	ns
88	L1CLK edge to L1SYNC valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)	_	0.00	ns

¹ The ratio SyncCLK/L1RCLK must be greater than 2.5/1.

⁴ These strobes and TxD on the first bit of the frame become valid after L1CLK edge or L1SYNC, whichever is later.

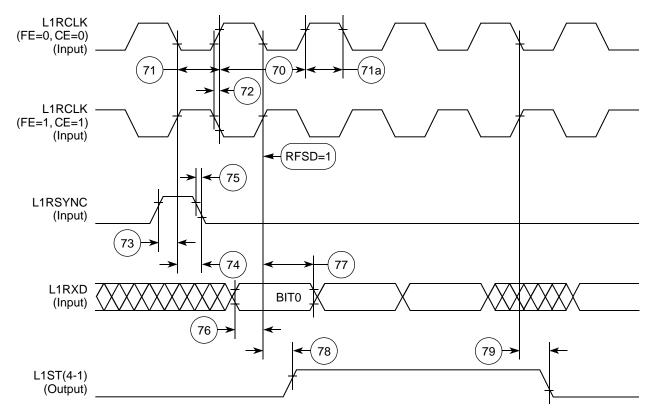


Figure 52. SI Receive Timing Diagram with Normal Clocking (DSC = 0)

² These specs are valid for IDL mode only.

Where $\dot{P} = 1/CLKOUT$. Thus for a 25-MHz CLKO1 rate, P = 40 ns.

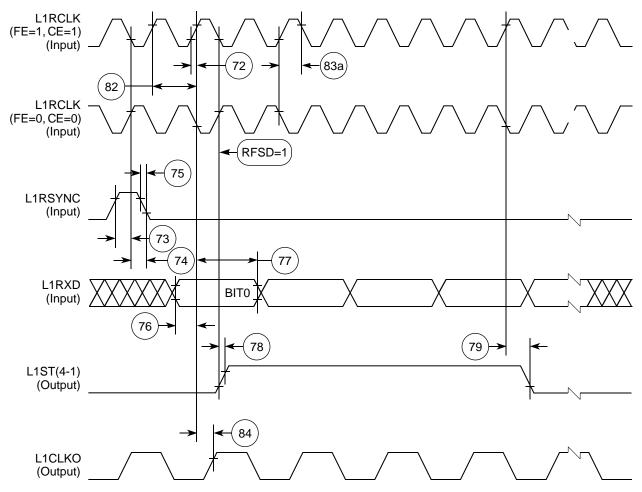


Figure 53. SI Receive Timing with Double-Speed Clocking (DSC = 1)

CPM Electrical CharacteristicsSerial Interface AC Electrical Specifications

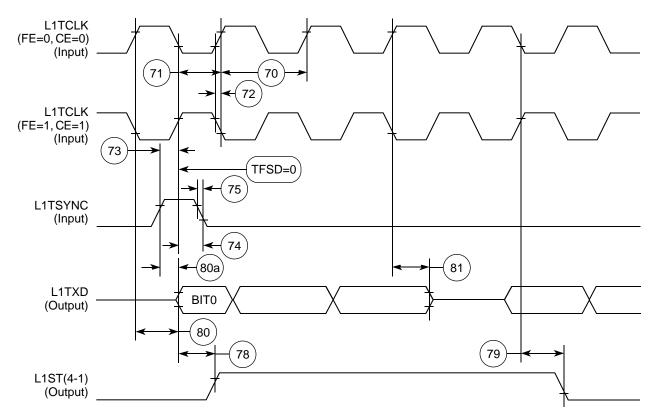


Figure 54. SI Transmit Timing Diagram (DSC = 0)

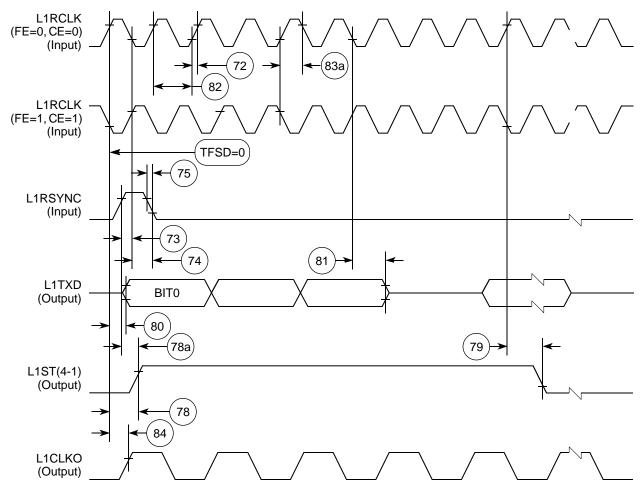


Figure 55. SI Transmit Timing with Double Speed Clocking (DSC = 1)

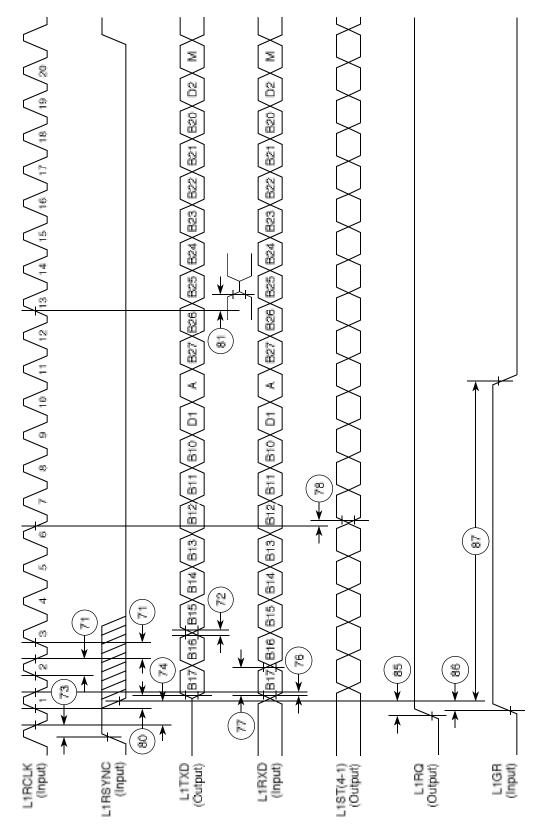


Figure 56. IDL Timing

11.7 SCC in NMSI Mode Electrical Specifications

Table 19 provides the NMSI external clock timing.

Table 19. NMSI External Clock Timing

Num	Characteristic	All Frequen	All Frequencies		
Num	Characteristic	Min	Max	Unit	
100	RCLK1 and TCLK1 width high ¹	1/SYNCCLK	_	ns	
101	RCLK1 and TCLK1 width low	1/SYNCCLK +5	_	ns	
102	RCLK1 and TCLK1 rise/fall time	_	15.00	ns	
103	TXD1 active delay (from TCLK1 falling edge)	0.00	50.00	ns	
104	RTS1 active/inactive delay (from TCLK1 falling edge)	0.00	50.00	ns	
105	CTS1 setup time to TCLK1 rising edge	5.00		ns	
106	RXD1 setup time to RCLK1 rising edge	5.00		ns	
107	RXD1 hold time from RCLK1 rising edge ²	5.00	<u> </u>	ns	
108	CD1 setup Time to RCLK1 rising edge	5.00	<u> </u>	ns	

¹ The ratios SyncCLK/RCLK1 and SyncCLK/TCLK1 must be greater than or equal to 2.25/1.

Table 20 provides the NMSI internal clock timing.

Table 20. NMSI Internal Clock Timing

Num	Characteristic	All Fr	Unit	
Num		Min	Max	Offic
100	RCLK1 and TCLK1 frequency ¹	0.00	SYNCCLK/3	MHz
102	RCLK1 and TCLK1 rise/fall time	_	_	ns
103	TXD1 active delay (from TCLK1 falling edge)	0.00	30.00	ns
104	RTS1 active/inactive delay (from TCLK1 falling edge)	0.00	30.00	ns
105	CTS1 setup time to TCLK1 rising edge	40.00	_	ns
106	RXD1 setup time to RCLK1 rising edge	40.00	_	ns
107	RXD1 hold time from RCLK1 rising edge ²	0.00	_	ns
108	CD1 setup time to RCLK1 rising edge	40.00	_	ns

The ratios SyncCLK/RCLK1 and SyncCLK/TCLK1 must be greater or equal to 3/1.

Figure 57 through Figure 59 show the NMSI timings.

² Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signal.

² Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signals.

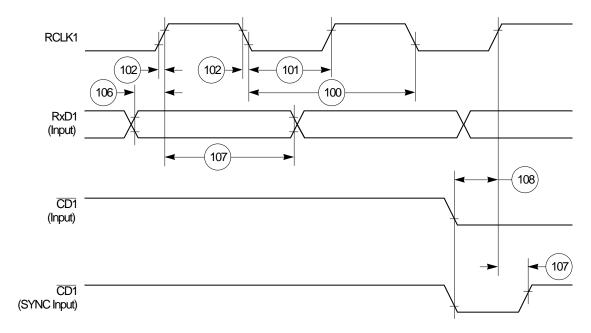


Figure 57. SCC NMSI Receive Timing Diagram

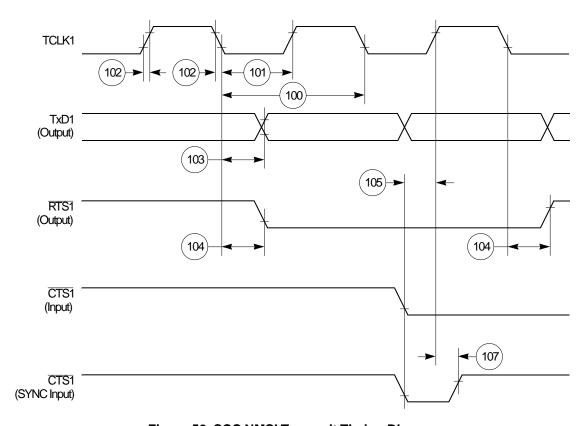


Figure 58. SCC NMSI Transmit Timing Diagram

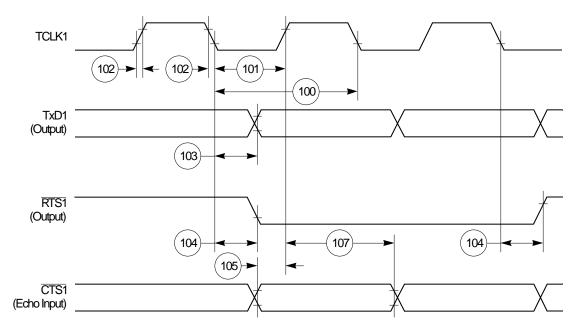


Figure 59. HDLC Bus Timing Diagram

11.8 Ethernet Electrical Specifications

Table 21 provides the Ethernet timings as shown in Figure 60 to Figure 64.

Table 21. Ethernet Timing

Num	Characteristic	All Frequencies		Unit
Num	Characteristic	Min	Max	Unit
120	CLSN width high	40	_	ns
121	RCLK1 rise/fall time	<u> </u>	15	ns
122	RCLK1 width low	40	_	ns
123	RCLK1 clock period ¹	80	120	ns
124	RXD1 setup time	20	_	ns
125	RXD1 hold time	5	_	ns
126	RENA active delay (from RCLK1 rising edge of the last data bit)	10	_	ns
127	RENA width low	100	_	ns
128	TCLK1 rise/fall time	_	15	ns
129	TCLK1 width low	40	_	ns
130	TCLK1 clock period ¹	99	101	ns
131	TXD1 active delay (from TCLK1 rising edge)	10	50	ns
132	TXD1 inactive delay (from TCLK1 rising edge)	10	50	ns
133	TENA active delay (from TCLK1 rising edge)	10	50	ns
134	TENA inactive delay (from TCLK1 rising edge)	10	50	ns
135	RSTRT active delay (from TCLK1 falling edge)	10	50	ns

CPM Electrical CharacteristicsEthernet Electrical Specifications

Table 21. Ethernet Timing (Continued)

Num	Characteristic		All Frequencies		
	Gilalacteristic	Min	Max	Unit	
136	RSTRT inactive delay (from TCLK1 falling edge)	10	50	ns	
137	REJECT width low	1	_	CLK	
138	CLKO1 low to SDACK asserted ²	_	20	ns	
139	CLKO1 low to SDACK negated ²	_	20	ns	

The ratios SyncCLK/RCLK1 and SyncCLK/TCLK1 must be greater or equal to 2/1.

² SDACK is asserted whenever the SDMA writes the incoming frame DA into memory.



Figure 60. Ethernet Collision Timing Diagram

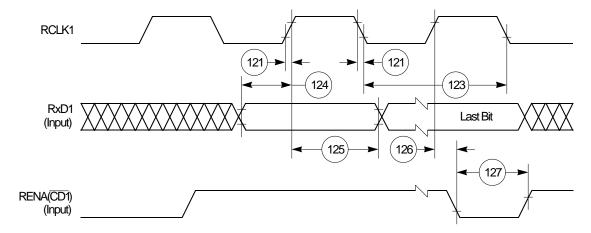
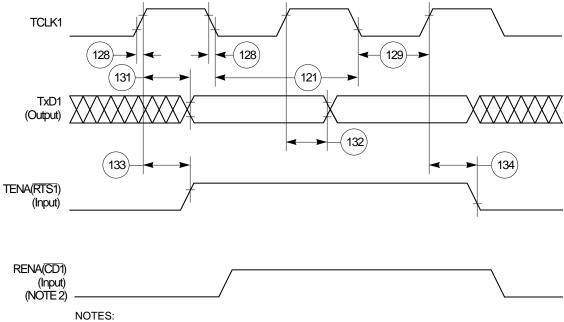


Figure 61. Ethernet Receive Timing Diagram



- 1. Transmit clock invert (TCI) bit in GSMR is set.
- If RENA is deasserted before TENA, or RENA is not asserted at all during transmit, then the CSL bit is set in the buffer descriptor at the end of the frame transmission.

Figure 62. Ethernet Transmit Timing Diagram

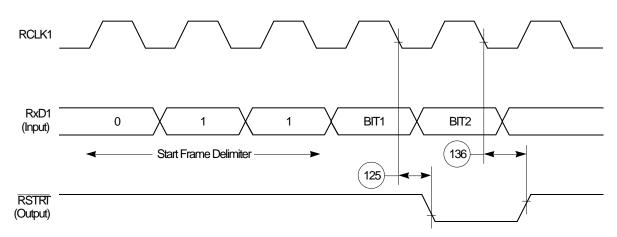


Figure 63. CAM Interface Receive Start Timing Diagram

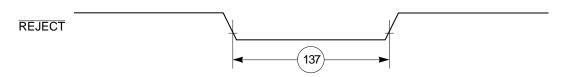


Figure 64. CAM Interface REJECT Timing Diagram

11.9 SMC Transparent AC Electrical Specifications

Table 22 provides the SMC transparent timings as shown in Figure 65.

Table 22. SMC Transparent Timing

Num	Characteristic	All Fred	All Frequencies		
	Characteristic		Max	Unit	
150	SMCLK clock period ¹	100	_	ns	
151	SMCLK width low	50	_	ns	
151A	SMCLK width high	50	<u> </u>	ns	
152	SMCLK rise/fall time	_	15	ns	
153	SMTXD active delay (from SMCLK falling edge)	10	50	ns	
154	SMRXD/SMSYNC setup time	20	<u> </u>	ns	
155	RXD1/SMSYNC hold time	5	<u> </u>	ns	

SyncCLK must be at least twice as fast as SMCLK.

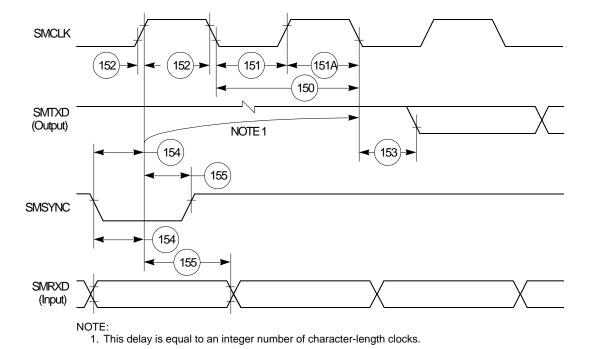


Figure 65. SMC Transparent Timing Diagram

11.10SPI Master AC Electrical Specifications

Table 23 provides the SPI master timings as shown in Figure 66 and Figure 67.

CPM Electrical CharacteristicsSPI Master AC Electrical Specifications

Table 23. SPI Master Timing

Num	Characteristic	All Frequ	Unit	
Num		Min	Max	Oilit
160	MASTER cycle time	4	1024	t _{cyc}
161	MASTER clock (SCK) high or low time	2	512	t _{cyc}
162	MASTER data setup time (inputs)	50	_	ns
163	Master data hold time (inputs)	0	_	ns
164	Master data valid (after SCK edge)	_	20	ns
165	Master data hold time (outputs)	0	_	ns
166	Rise time output	_	15	ns
167	Fall time output	_	15	ns

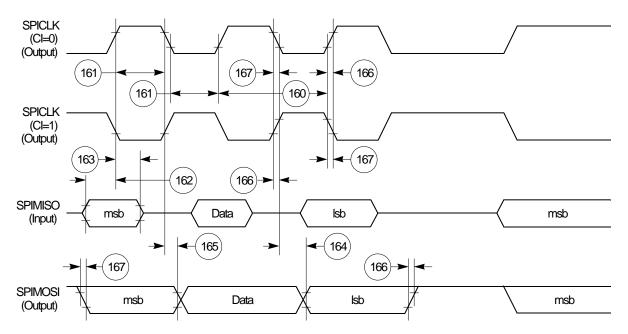


Figure 66. SPI Master (CP = 0) Timing Diagram

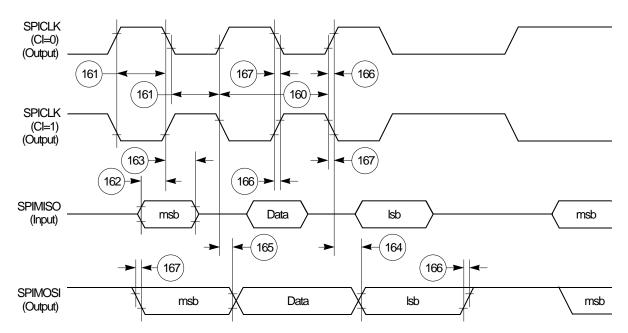


Figure 67. SPI Master (CP = 1) Timing Diagram

11.11SPI Slave AC Electrical Specifications

Table 24 provides the SPI slave timings as shown in Figure 68 and Figure 69.

Table 24. SPI Slave Timing

Num	Characteristic		All Frequencies	
Italii			Max	Unit
170	Slave cycle time	2	_	t _{cyc}
171	Slave enable lead time	15	_	ns
172	Slave enable lag time	15	_	ns
173	Slave clock (SPICLK) high or low time	1	_	t _{cyc}
174	Slave sequential transfer delay (does not require deselect)	1	_	t _{cyc}
175	Slave data setup time (inputs)	20	_	ns
176	Slave data hold time (inputs)	20	_	ns
177	Slave access time	_	50	ns

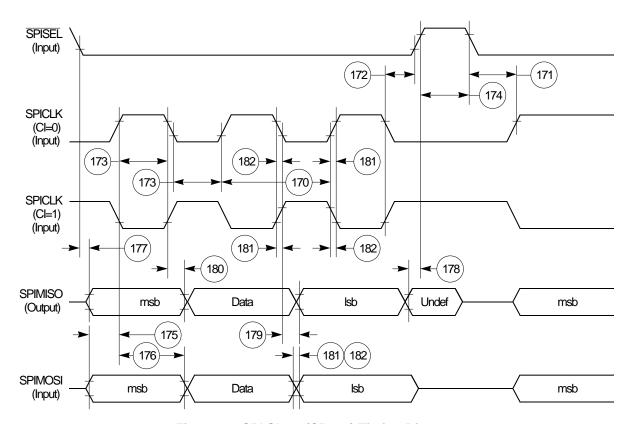
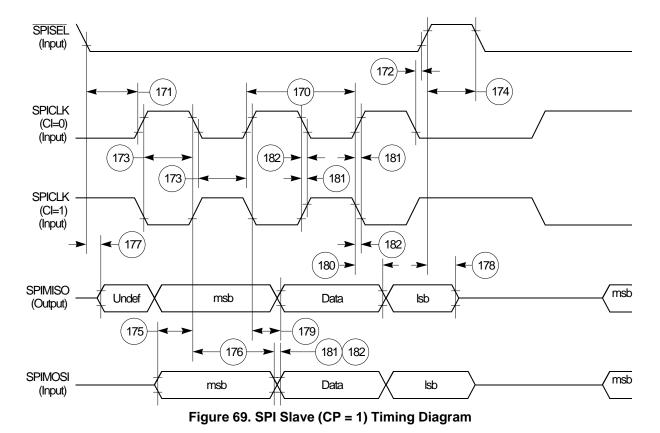


Figure 68. SPI Slave (CP = 0) Timing Diagram



11.12I²C AC Electrical Specifications

Table 25 provides the I²C (SCL < 100 KHz) timings.

Table 25. I²C Timing (SCL < 100 KHz)

Num	Characteristic	All Fred	All Frequencies		
Num	Cital acteristic	Min	Max	Unit	
200	SCL clock frequency (slave)	0	100	KHz	
200	SCL clock frequency (master) ¹	1.5	100	KHz	
202	Bus free time between transmissions	4.7	_	μs	
203	Low period of SCL	4.7	_	μs	
204	High period of SCL	4.0	_	μs	
205	Start condition setup time	4.7	_	μs	
206	Start condition hold time	4.0	_	μs	
207	Data hold time	0	_	μs	
208	Data setup time	250	_	ns	
209	SDL/SCL rise time	_	1	μs	
210	SDL/SCL fall time	_	300	ns	
211	Stop condition setup time	4.7	_	μs	

SCL frequency is given by SCL = BRGCLK_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(BRGCLK/pre_scaler) must be greater or equal to 4/1.

Table 26 provides the I^2C (SCL > 100 KHz) timings.

Table 26. I^2C Timing (SCL > 100 KHz)

Num	Characteristic	Expression	All Fre	Unit	
Num		Expression	Min	Max	- Onit
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz
200	SCL clock frequency (master) ¹	fSCL	BRGCLK/16512	BRGCLK/48	Hz
202	Bus free time between transmissions	_	1/(2.2 * fSCL)	_	s
203	Low period of SCL	_	1/(2.2 * fSCL)	_	s
204	High period of SCL	_	1/(2.2 * fSCL)	_	s
205	Start condition setup time	_	1/(2.2 * fSCL)	_	s
206	Start condition hold time	_	1/(2.2 * fSCL)	_	s
207	Data hold time	_	0	_	s
208	Data setup time	_	1/(40 * fSCL)	_	s
209	SDL/SCL rise time	_	_	1/(10 * fSCL)	s
210	SDL/SCL fall time	_	_	1/(33 * fSCL)	s
211	Stop condition setup time	_	1/2(2.2 * fSCL)	_	s

SCL frequency is given by SCL = BrgClk_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(Brg_Clk/pre_scaler) must be greater or equal to 4/1.

Figure 70 shows the I²C bus timing.

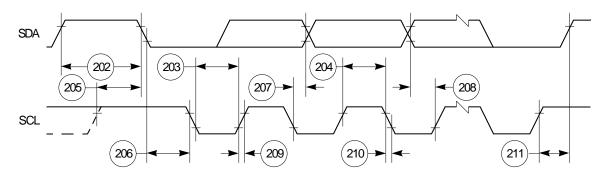


Figure 70. I²C Bus Timing Diagram

Part XII UTOPIA AC Electrical Specifications

Table 27 shows the AC electrical specifications for the UTOPIA interface.

Table 27. UTOPIA AC Electrical Specifications

Num	Signal Characteristic	Direction	Min	Max	Unit
U1	UtpClk rise/fall time (Internal clock option)	Output		4ns	ns
	Duty cycle		50	50	%
	Frequency			50	Mhz
U1a	UtpClk rise/fall time (external clock option)	Input		4ns	ns
	Duty cycle		40	60	%
	Frequency			50	Mhz
U2	RxEnb and TxEnb active delay	Output	2ns	16ns	ns
U3	UTPB, SOC, Rxclav and Txclav setup time	Input	4ns		ns
U4	UTPB, SOC, Rxclav and Txclav hold time	Input	1ns		ns
U5	UTPB, SOC active delay (and PHREQ and PHSEL active delay in MPHY mode)	Output	2ns	16ns	ns

Figure 71 shows signal timings during UTOPIA receive operations.

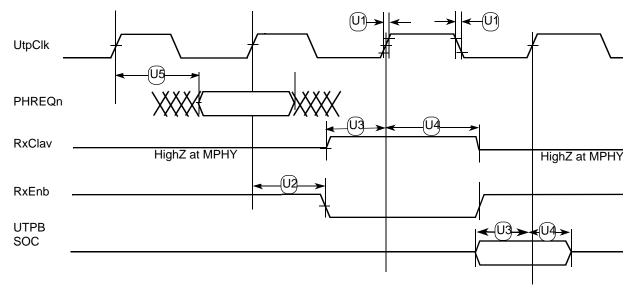


Figure 71. UTOPIA Receive Timing

Figure 72 shows signal timings during UTOPIA transmit operations.

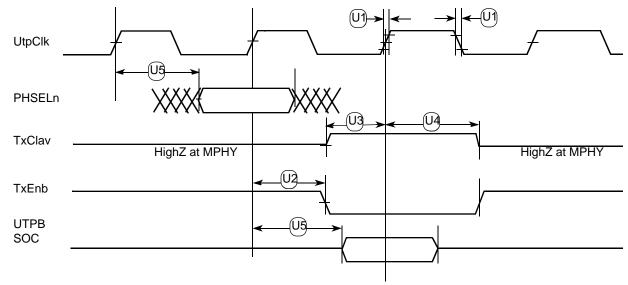


Figure 72. UTOPIA Transmit Timing

Part XIII FEC Electrical Characteristics

This section provides the AC electrical specifications for the Fast Ethernet controller (FEC). Note that the timing specifications for the MII signals are independent of system clock frequency (part speed designation). Also, MII signals use TTL signal levels compatible with devices operating at 3.3 V.

13.1 MII Receive Signal Timing (MII_RXD[3:0], MII_RX_DV, MII_RX_ER, MII_RX_CLK)

The receiver functions correctly up to a MII_RX_CLK maximum frequency of 25MHz +1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_RX_CLK frequency - 1%.

Table 28 provides information on the MII receive signal timing.

Table 28. MII Receive Signal Timing

Num	Characteristic	Min	Max	Unit
M1	MII_RXD[3:0], MII_RX_DV, MII_RX_ER to MII_RX_CLK setup	5	_	ns
M2	MII_RX_CLK to MII_RXD[3:0], MII_RX_DV, MII_RX_ER hold	5	_	ns
М3	MII_RX_CLK pulse width high	35%	65%	MII_RX_CLK period
M4	MII_RX_CLK pulse width low	35%	65%	MII_RX_CLK period

Figure 73 shows MII receive signal timing.

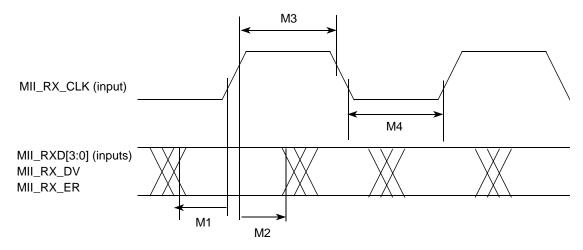


Figure 73. MII Receive Signal Timing Diagram

13.2 MII Transmit Signal Timing (MII_TXD[3:0], MII_TX_EN, MII_TX_ER, MII_TX_CLK)

The transmitter functions correctly up to a MII_TX_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_TX_CLK frequency - 1%.

Table 29 provides information on the MII transmit signal timing,.

Table 29. MII Transmit Signal Timing

Num	Characteristic	Min	Max	Unit
M5	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER invalid	5	_	ns
M6	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER valid	_	25	
M7	MII_TX_CLK pulse width high	35%	65%	MII_TX_CLK period
M8	MII_TX_CLK pulse width low	35%	65%	MII_TX_CLK period

Figure 74 shows the MII transmit signal timing diagram.

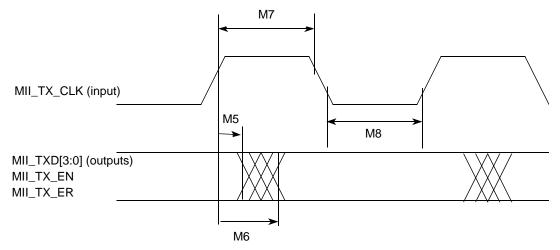


Figure 74. MII Transmit Signal Timing Diagram

13.3 MII Async Inputs Signal Timing (MII_CRS, MII_COL)

Table 30 provides information on the MII async inputs signal timing.

Table 30. MII Async Inputs Signal Timing

Num	Characteristic	Min	Max	Unit
M9	MII_CRS, MII_COL minimum pulse width	1.5	1	MII_TX_CLK period

Figure 75 shows the MII asynchronous inputs signal timing diagram.

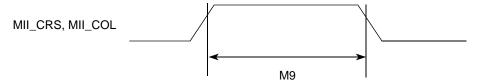


Figure 75. MII Async Inputs Timing Diagram

13.4 MII Serial Management Channel Timing (MII_MDIO, MII_MDC)

Table 31 provides information on the MII serial management channel signal timing. The FEC functions correctly with a maximum MDC frequency in excess of 2.5 MHz. The exact upper bound is under investigation.

Table 31. MII Serial Management Channel Timing

Num	Characteristic	Min	Max	Unit
M10	MII_MDC falling edge to MII_MDIO output invalid (minimum propagation delay)	0	_	ns
M11	MII_MDC falling edge to MII_MDIO output valid (max prop delay)	_	25	ns
M12	MII_MDIO (input) to MII_MDC rising edge setup	10	_	ns

0

40%

40%

ns

MII_MDC period

MII_MDC period

60%

60%

Figure 76 shows the MII serial management channel timing diagram.

MII_MDIO (input) to MII_MDC rising edge hold

MII_MDC pulse width high

MII_MDC pulse width low

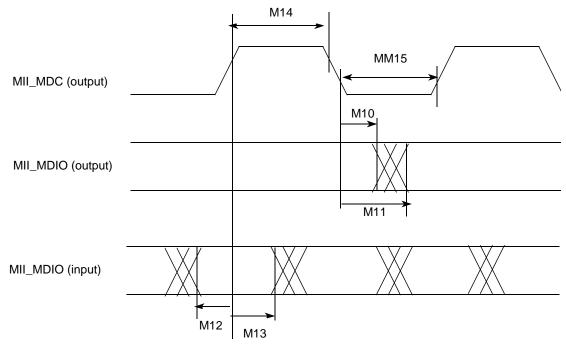


Figure 76. MII Serial Management Channel Timing Diagram

M13

M14

M15

Part XIV Mechanical Data and Ordering Information

Table 32 provides information on the MPC857T and MPC857DSL.

Table 32. MPC857T

Device	Number of	Ethernet	Multi-Channel	A I M SUPPORT	Cach	e Size
Device	SCCs 1	Support	HDLC Support	ATM Support	Instruction	Data
MPC857T	One (SCC1)	10/100 Mbps	Yes	Yes	4 Kbyte	4 Kbyte
MPC857DSL	One (SCC1)	10/100 Mbps	No	Up to 4 addresses	4 Kbyte	4 Kbyte

¹ Serial communications controller (SCC)

Table 33 identifies the packages and operating frequencies available for the MPC857T (part number information for the MPC857DSL is TBD at this time).

Table 33. MPC857T Package/Frequency Availability

Package Type	Temperature (Tj)	Frequency (MHz)	Order Number
Ball grid array	0°C to 95°C	50	XPC857TZP50
(ZP suffix)		66	XPC857TZP66
		80	XPC857TZP80
Ball grid array	-40°C to 95°C	50	XPC857TCZP50
(CZP suffix)		66	XPC857TCZP66

14.1 Pin Assignments

Figure 77 shows the top view pinout of the PBGA package. For additional information, see the *MPC857T PowerQUICC User s Manual*.

NOTE: This is the top view of the device.

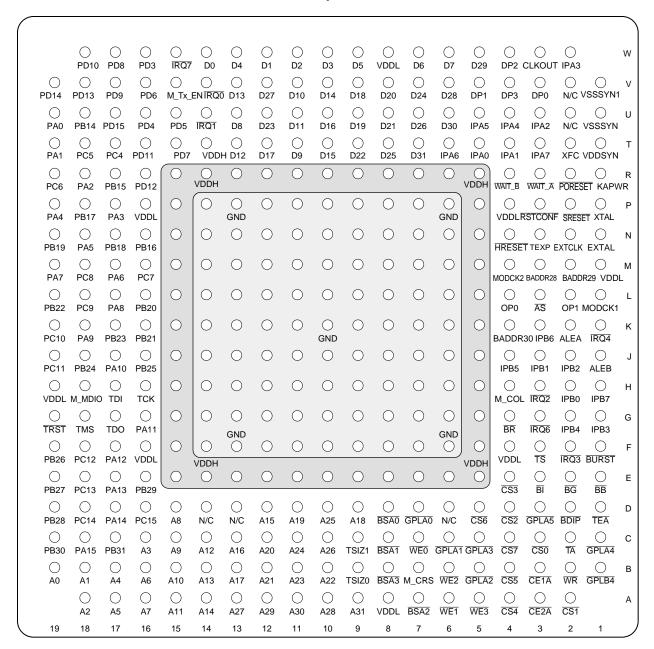


Figure 77. Pinout of the PBGA Package

Table 34 contains a list of the MPC857T input and output signals and shows multiplexing and pin assignments.

Table 34. Pin Assignments

Name	Pin Number	Туре
A[0:31]	B19, B18, A18, C16, B17, A17, B16, A16, D15, C15, B15, A15, C14, B14, A14, D12, C13, B13, D9, D11, C12, B12, B10, B11, C11, D10, C10, A13, A10, A12, A11, A9	Bidirectional Three-state
TSIZ0 REG	B9	Bidirectional Three-state
TSIZ1	C9	Bidirectional Three-state
RD/WR	B2	Bidirectional Three-state
BURST	F1	Bidirectional Three-state
BDIP GPL_B5	D2	Output
TS	F3	Bidirectional Active Pull-up
TA	C2	Bidirectional Active Pull-up
TEA	D1	Open-drain
BI	E3	Bidirectional Active Pull-up
IRQ2 RSV	H3	Bidirectional Three-state
IRQ4 KR RETRY SPKROUT	K1	Bidirectional Three-state
CR IRQ3	F2	Input
D[0:31]	W14, W12, W11, W10, W13, W9, W7, W6, U13, T11, V11, U11, T13, V13, V10, T10, U10, T12, V9, U9, V8, U8, T9, U12, V7, T8, U7, V12, V6, W5, U6, T7	Bidirectional Three-state
DP0 IRQ3	V3	Bidirectional Three-state
DP1 IRQ4	V5	Bidirectional Three-state
DP2 IRQ5	W4	Bidirectional Three-state
DP3 IRQ6	V4	Bidirectional Three-state
BR	G4	Bidirectional
BG	E2	Bidirectional
BB	E1	Bidirectional Active Pull-up

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
FRZ ĪRQ6	G3	Bidirectional
ĪRQ0	V14	Input
IRQ1	U14	Input
M_TX_CLK IRQ7	W15	Input
<u>CS</u> [0:5]	C3, A2, D4, E4, A4, B4	Output
CS6 CE1_B	D5	Output
CS7 CE2_B	C4	Output
WEO BS_BO IORD	C7	Output
WE1 BS_B1 IOWR	A6	Output
WE2 BS_B2 PCOE	B6	Output
WE3 BS_B3 PCWE	A5	Output
BS_A[0:3]	D8, C8, A7, B8	Output
GPL_A0 GPL_B0	D7	Output
OE GPL_A1 GPL_B1	C6	Output
GPL_A[2:3] GPL_B[2:3] CS[2-3]	B5, C5	Output
UPWAITA GPL_A4	C1	Bidirectional
UPWAITB GPL_B4	B1	Bidirectional
GPL_A5	D3	Output
PORESET	R2	Input
RSTCONF	P3	Input
HRESET	N4	Open-drain
SRESET	P2	Open-drain
XTAL	P1	Analog Output

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
EXTAL	N1	Analog Input (3.3V only)
XFC	T2	Analog Input
CLKOUT	W3	Output
EXTCLK	N2	Input (3.3V only)
TEXP	N3	Output
ALE_A MII-TXD1	K2	Output
CE1_A MII-TXD2	B3	Output
CE2_A MII-TXD3	A3	Output
WAIT_A SOC_Split ²	R3	Input
WAIT_B	R4	Input
IP_A0 UTPB_Split0 ² MII-RXD3	T5	Input
IP_A1 UTPB_Split1 ² MII-RXD2	T4	Input
IP_A2 IOIS16_A UTPB_Split2 ² MII-RXD1	U3	Input
IP_A3 UTPB_Split3 ² MII-RXD0	W2	Input
IP_A4 UTPB_Split4 ² MII-RXCLK	U4	Input
IP_A5 UTPB_Split5 ² MII-RXERR	U5	Input
IP_A6 UTPB_Split6 ² MII-TXERR	T6	Input
IP_A7 UTPB_Split7 ² MII-RXDV	ТЗ	Input
ALE_B DSCK/AT1	J1	Bidirectional Three-state
IP_B[0:1] IWP[0:1] VFLS[0:1]	H2, J3	Bidirectional

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
IP_B2 IOIS16_B AT2	J2	Bidirectional Three-state
IP_B3 IWP2 VF2	G1	Bidirectional
IP_B4 LWP0 VF0	G2	Bidirectional
IP_B5 LWP1 VF1	J4	Bidirectional
IP_B6 DSDI AT0	K3	Bidirectional Three-state
IP_B7 PTR AT3	H1	Bidirectional Three-state
OP0 MII-TXD0 UtpClk_Split ²	L4	Bidirectional
OP1	L2	Output
OP2 MODCK1 STS	L1	Bidirectional
OP3 MODCK2 DSDO	M4	Bidirectional
BADDR30 REG	K4	Output
BADDR[28:29]	M3, M2	Output
ĀS	L3	Input
PA15 RXD1	C18	Bidirectional
PA14 TXD1	D17	Bidirectional (Optional: Open-drain)
PA13	E17	Bidirectional
PA12	F17	Bidirectional (Optional: Open-drain)
PA11	G16	Bidirectional (Optional: Open-drain)

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
PA10	J17	Bidirectional
PA9 L1TXDA	K18	Bidirectional (Optional: Open-drain)
PA8 L1RXDA	L17	Bidirectional
PA7 CLK1 L1RCLKA BRGO1 TIN1	M19	Bidirectional
PA6 CLK2 TOUT1	M17	Bidirectional
PA5 CLK3 L1TCLKA BRGO2 TIN2	N18	Bidirectional
PA4 CLK4 TOUT2	P19	Bidirectional
PA3 CLK5 BRGO3 TIN3	P17	Bidirectional
PA2 CLK6 TOUT3	R18	Bidirectional
PA1 CLK7 BRGO4 TIN4	T19	Bidirectional
PA0 CLK8 TOUT4	U19	Bidirectional
PB31 SPISEL REJECT1	C17	Bidirectional (Optional: Open-drain)
PB30 SPICLK RSTRT2	C19	Bidirectional (Optional: Open-drain)
PB29 SPIMOSI	E16	Bidirectional (Optional: Open-drain)
PB28 SPIMISO BRGO4	D19	Bidirectional (Optional: Open-drain)

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
PB27 I2CSDA BRGO1	E19	Bidirectional (Optional: Open-drain)
PB26 I2CSCL BRGO2	F19	Bidirectional (Optional: Open-drain)
PB25 RXADDR3 ² SMTXD1	J16	Bidirectional (Optional: Open-drain)
PB24 TXADDR3 ² SMRXD1	J18	Bidirectional (Optional: Open-drain)
PB23 TXADDR2 ² SDACK1 SMSYN1	K17	Bidirectional (Optional: Open-drain)
PB22 TXADDR4 ² SDACK2 SMSYN2	L19	Bidirectional (Optional: Open-drain)
PB21 SMTXD2 PHSEL1 ¹ TXADDR1 ²	K16	Bidirectional (Optional: Open-drain)
PB20 SMRXD2 L1CLKOA PHSEL0 ¹ TXADDR0 ²	L16	Bidirectional (Optional: Open-drain)
PB19 RTS1 L1ST1	N19	Bidirectional (Optional: Open-drain)
PB18 RXADDR4 ² L1ST2	N17	Bidirectional (Optional: Open-drain)
PB17 L1ST3 PHREQ1 ¹ RXADDR1 ²	P18	Bidirectional (Optional: Open-drain)
PB16 L1RQa L1ST4 PHREQ0 ¹ RXADDR0 ²	N16	Bidirectional (Optional: Open-drain)
PB15 BRGO3 TxClav	R17	Bidirectional

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
PB14 RXADDR2 ² RSTRT1	U18	Bidirectional
PC15 DREQ0 RTS1 L1ST1 RxClav	D16	Bidirectional
PC14 DREQ1 L1ST2	D18	Bidirectional
PC13 L1ST3	E18	Bidirectional
PC12 L1RQa L1ST4	F18	Bidirectional
PC11 CTS1	J19	Bidirectional
PC10 CD1 TGATE1	K19	Bidirectional
PC9	L18	Bidirectional
PC8 TGATE2	M18	Bidirectional
PC7 SDACK2	M16	Bidirectional
PC6	R19	Bidirectional
PC5 L1TSYNCA SDACK1	T18	Bidirectional
PC4 CD4 L1RSYNCA	T17	Bidirectional
PD15 L1TSYNCA MII-RXD3 UTPB0	U17	Bidirectional
PD14 L1RSYNCA MII-RXD2 UTPB1	V19	Bidirectional
PD13 MII-RXD1 UTPB2	V18	Bidirectional

Table 34. Pin Assignments (Continued)

Name	Pin Number	Туре
PD12 MII-MDC UTPB3	R16	Bidirectional
PD11 MII-TXERR RXENB	T16	Bidirectional
PD10 MII-RXD0 TXENB	W18	Bidirectional
PD9 MII-TXD0 UTPCLK	V17	Bidirectional
PD8 MII-MDC MII-RXCLK	W17	Bidirectional
PD7 MII-RXERR UTPB4	T15	Bidirectional
PD6 MII-RXDV UTPB5	V16	Bidirectional
PD5 REJECT2 MII-TXD3 UTPB6	U15	Bidirectional
PD4 REJECT3 MII-TXD2 UTPB7	U16	Bidirectional
PD3 REJECT4 MII-TXD1 SOC	W16	Bidirectional
TMS	G18	Input
TDI DSDI	H17	Input
TCK DSCK	H16	Input
TRST	G19	Input
TDO DSDO	G17	Output
M_CRS	B7	Input
M_MDIO	H18	Bidirectional
M_TXEN	V15	Output
M_COL	H4	Input

Mechanical Data and Ordering InformationMechanical Dimensions of the PBGA Package

Table 34. Pin Assignments (Continued)

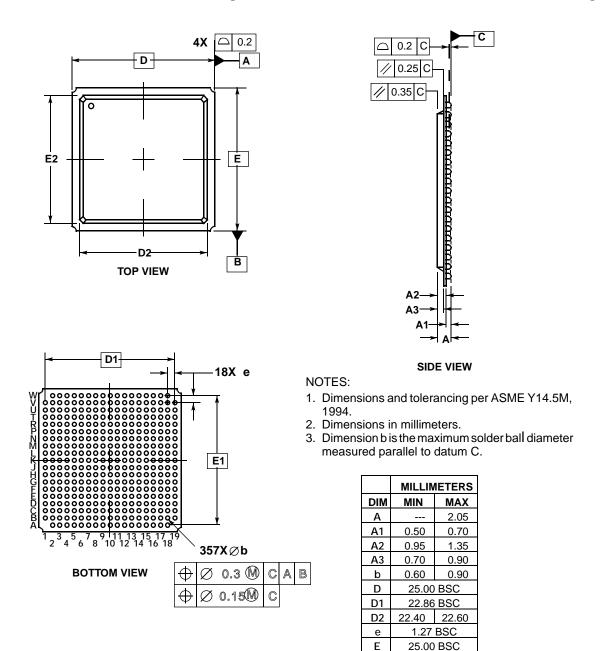
Name	Pin Number	Туре
KAPWR	R1	Power
GND	F6, F7, F8, F9, F10, F11, F12, F13, F14, G6, G7, G8, G9, G10, G11, G12, G13, G14, H6, H7, H8, H9, H10, H11, H12, H13, H14, J6, J7, J8, J9, J10, J11, J12, J13, J14, K6, K7, K8, K9, K10, K11, K12, K13, K14, L6, L7, L8, L9, L10, L11, L12, L13, L14, M6, M7, M8, M9, M10, M11, M12, M13, M14, N6, N7, N8, N9, N10, N11, N12, N13, N14, P6, P7, P8, P9, P10, P11, P12, P13, P14	Power
VDDL	A8, M1, W8, H19, F4, F16, P4, P16	Power
VDDH	E5, E6, E7, E8, E9, E10, E11, E12, E13, E14, E15, F5, F15, G5, G15, H5, H15, J5, J15, K5, K15, L5, L15, M5, M15, N5, N15, P5, P15, R5, R6, R7, R8, R9, R10, R11, R12, R13, R14, R15, T14	Power
N/C	D6, D13, D14, U2, V2	No-connect

¹ Classic SAR mode only

14.2 Mechanical Dimensions of the PBGA Package

For more information on the printed circuit board layout of the PBGA package, including thermal via design and suggested pad layout, please refer to *Plastic Ball Grid Array Application Note* (order number: AN1231/D) available from your local Motorola sales office. Figure 78 shows the mechanical dimensions of the PBGA package.

² ESAR mode only



Case No. 1103-01

Figure 78. Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package

E1

E2

22.86 BSC

22.40 22.60

Part XV Document Revision History

Table 35 lists significant changes between revisions of this document.

Table 35. Document Revision History

Revision	Date	Change
0	2001	Initial revision
0.1	9/2001	Change extended temperature from 95 to 105
0.2	11/2001	Revised for new template and added the MPC857DSL. Corrected Table 6, B23 @ 66Mhz to the max value of 8ns.
0.3	6/2002	Changed verbiage on MPC857DSL, that it contains SMC1 and not SMC2



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